

MEMS 光制御技術の研究動向

(静電マイクロアクチュエータの光学応用)

年吉 洋

Hiroshi TOSHIYOSHI

東京大学 先端科学技術研究センター
Research Center for Advanced Science and Technology (RCAST)
The University of Tokyo

東京大学 生産技術研究所
マイクロナノメカトロニクス国際研究センター
Center for International Research on Micronano Mechatronics
Institute of Industrial Science
The University of Tokyo

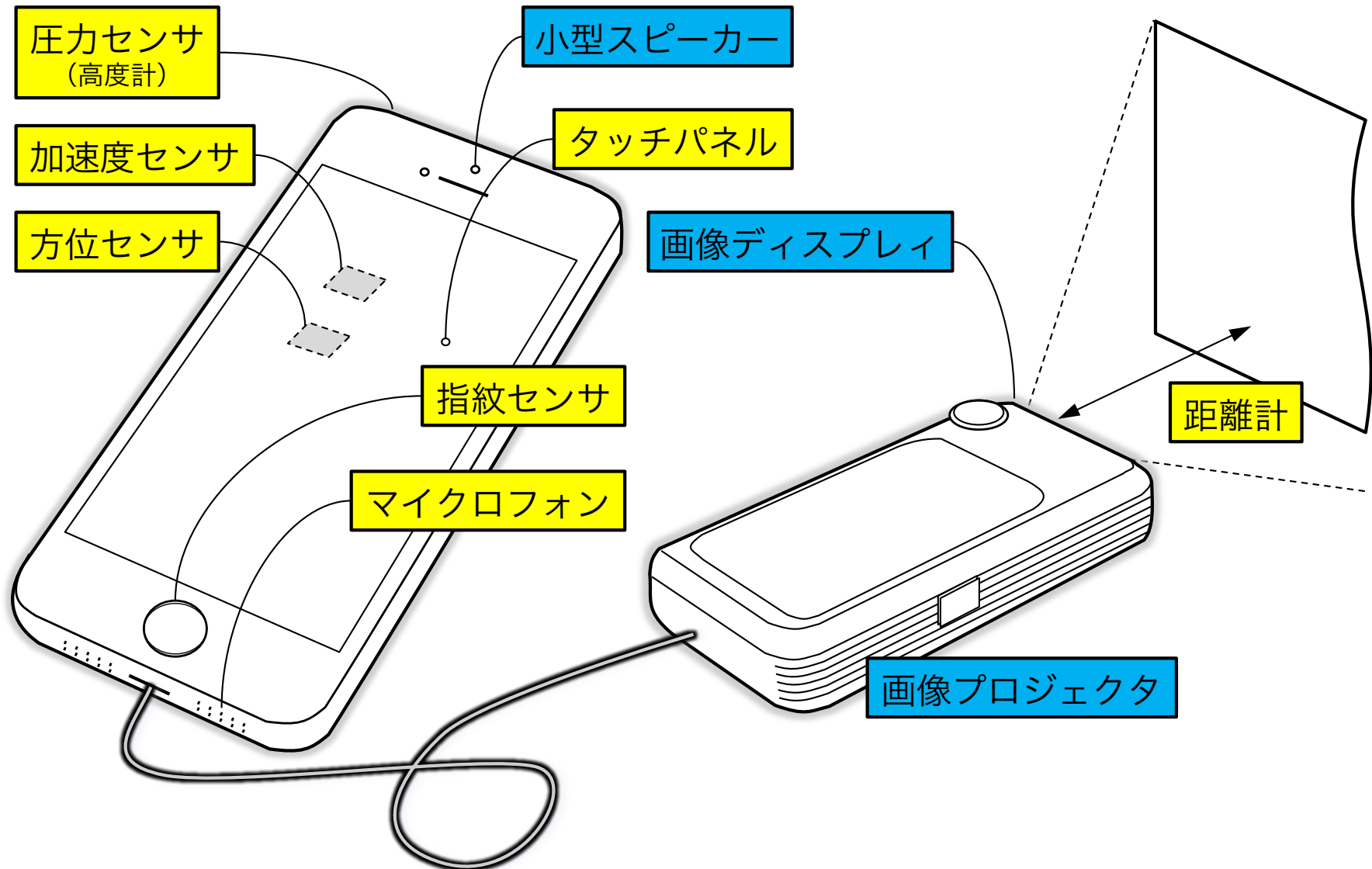
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- 3. MEMS at the Beginning = Fiber Telecom
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- 5. More Added Values
- 6. Summary

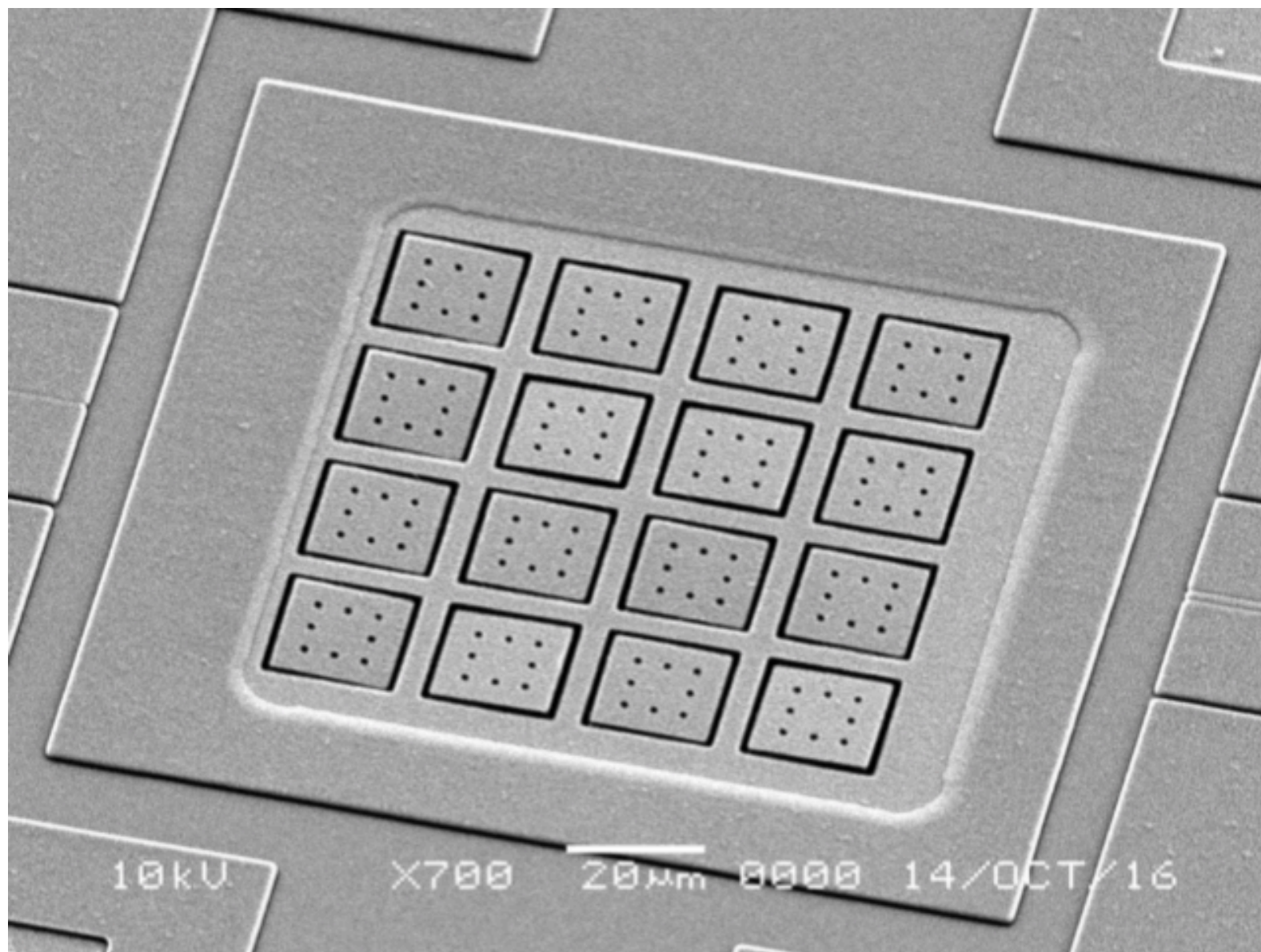
ケータイ／スマホの部品、実世界とのI/OはMEMS

センサ

アクチュエータ

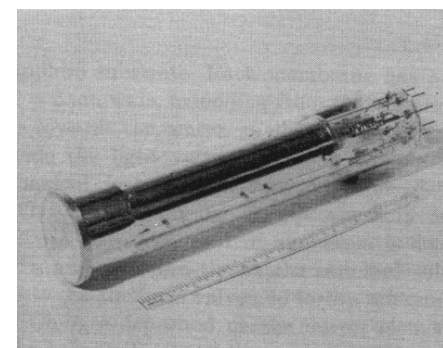
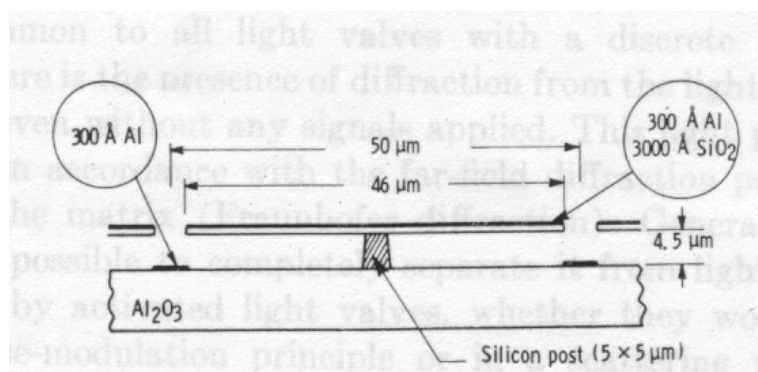
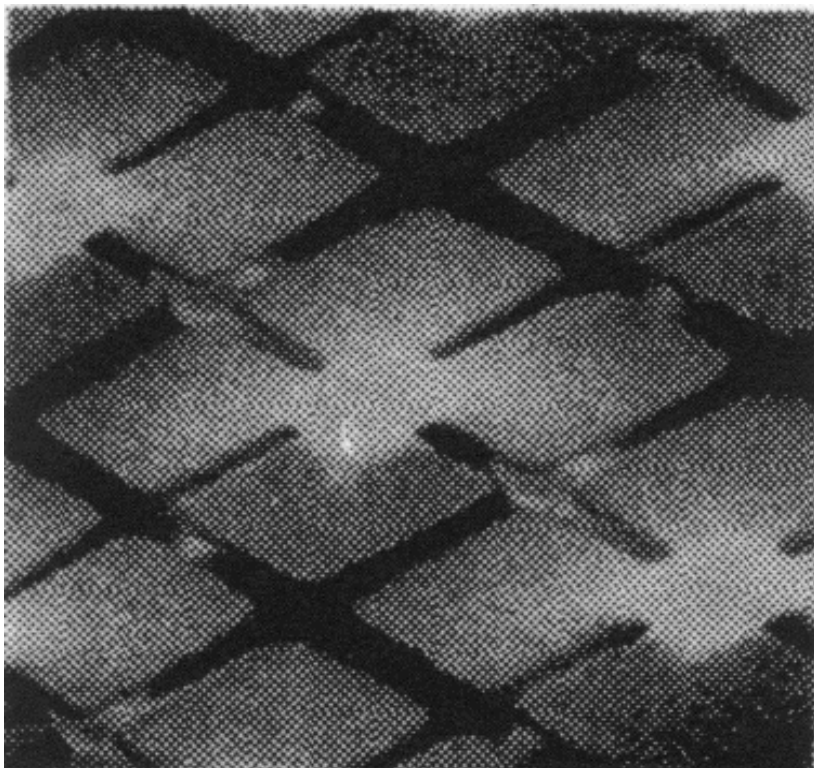


CMOS-MEMSマイクロミラーはじめました



Projection Display in 1975

R. N. Thomas, J. Guldberg, H. C. Nathanson, P. R. Malmberg, IEEE Trans. ED vol. 22, 1975, Westinghouse Research Labs & Philips

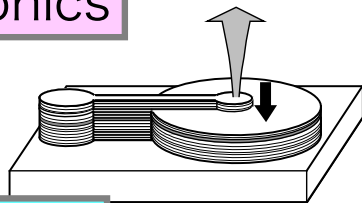


A True Micro Motor, Diameter 120 microns

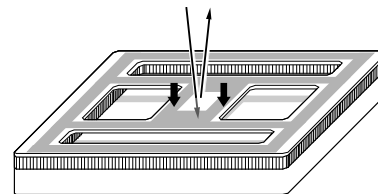


Y.Tai et al. Sensors & Actuators 1989

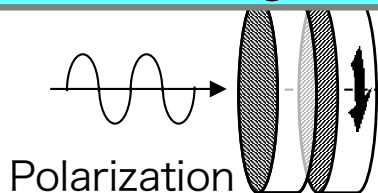
Quantum Photonics



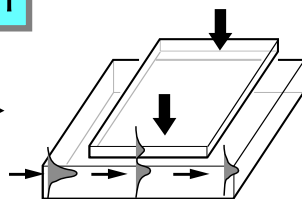
Emission
Absorption



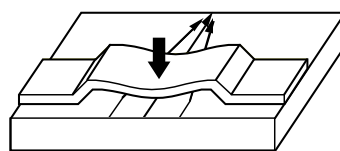
Electromagnetism



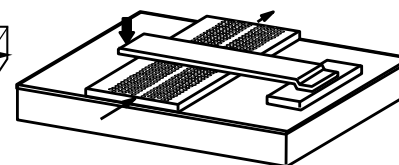
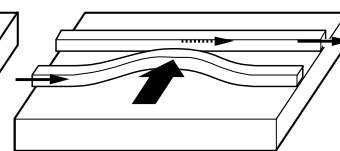
Polarization



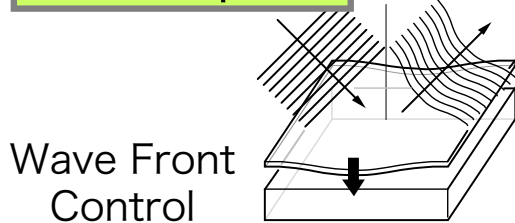
Absorption



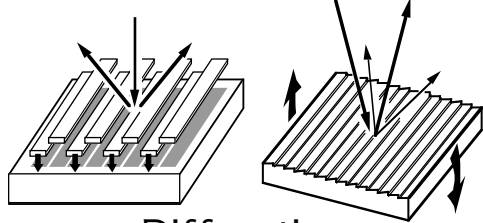
Near Field Optics, Plasmon Resonance, Metamaterial



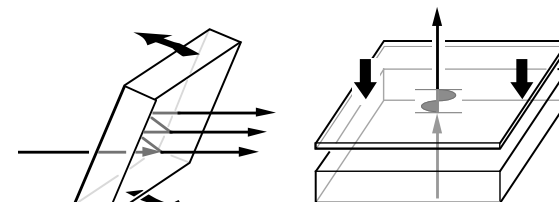
Wave Optics



Wave Front
Control



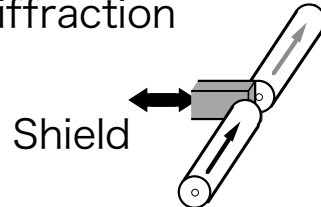
Diffraction



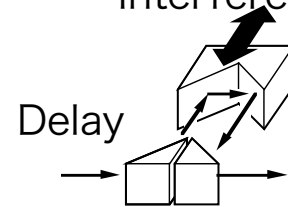
Interference



Coupling

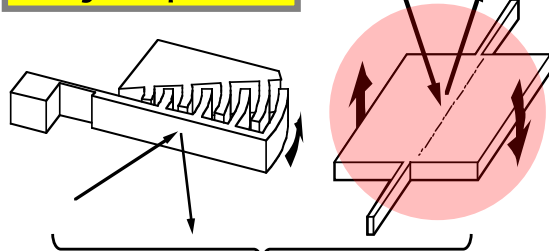


Shield

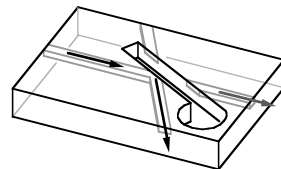


Delay

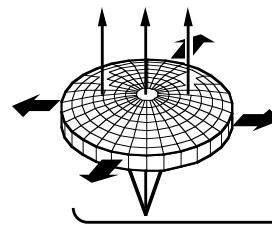
Ray Optics



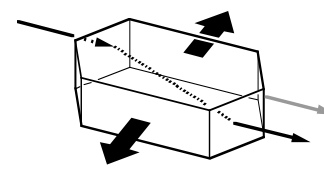
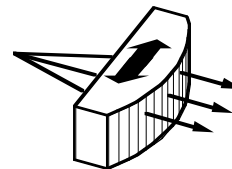
Reflection



T.I.R

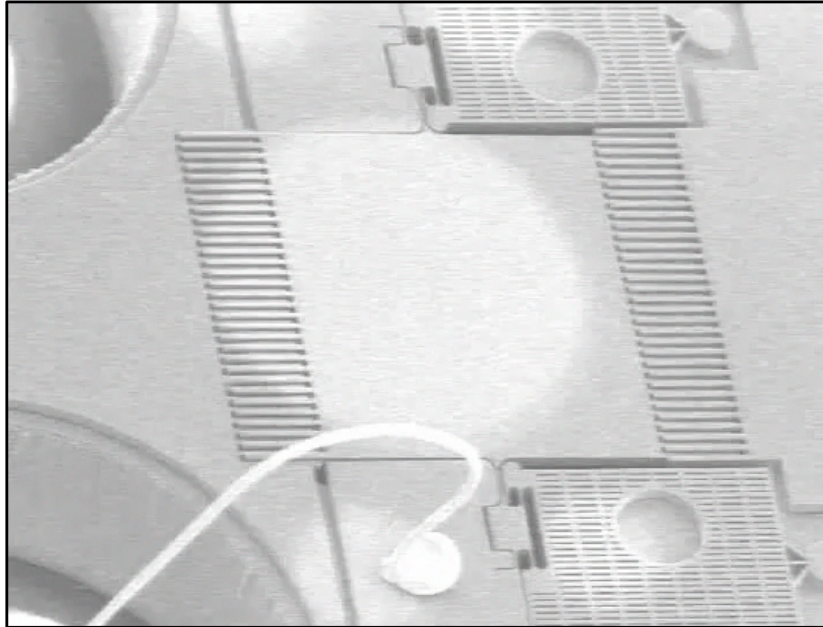


Refraction

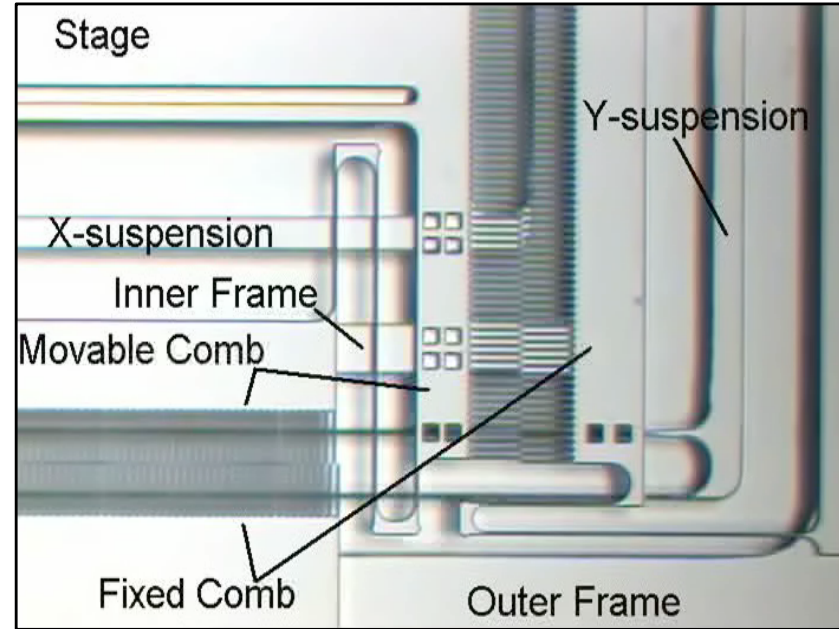


MEMS Micro Actuators

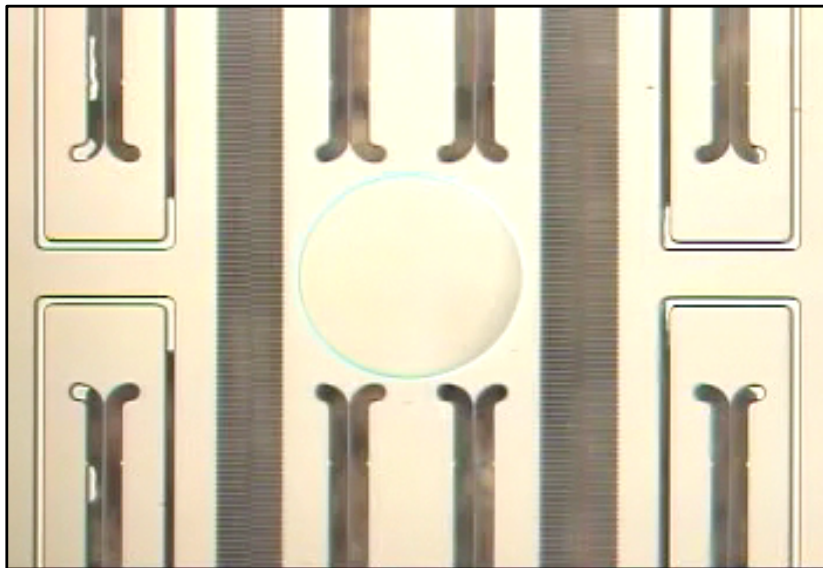
MEMS = Micro Electro Mechanical Systems



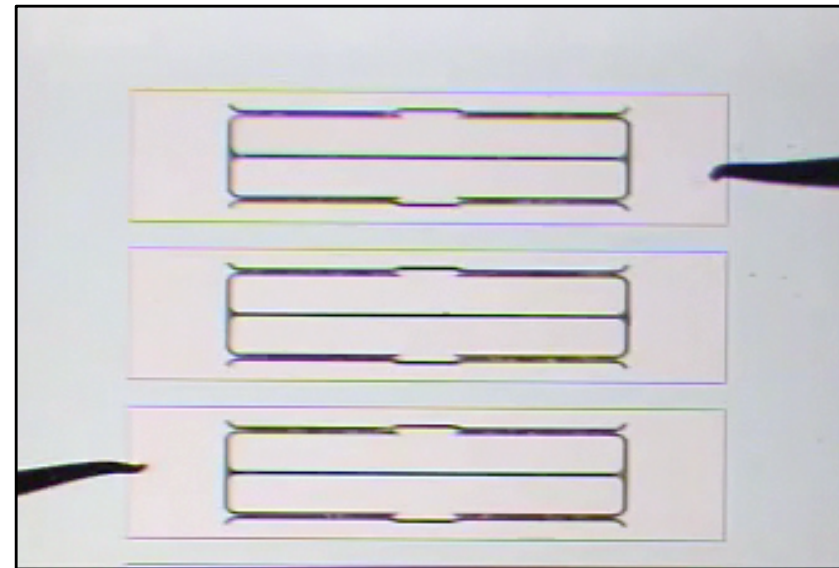
K. Isamoto, Santec Corp.,



K. Takahashi, 2007



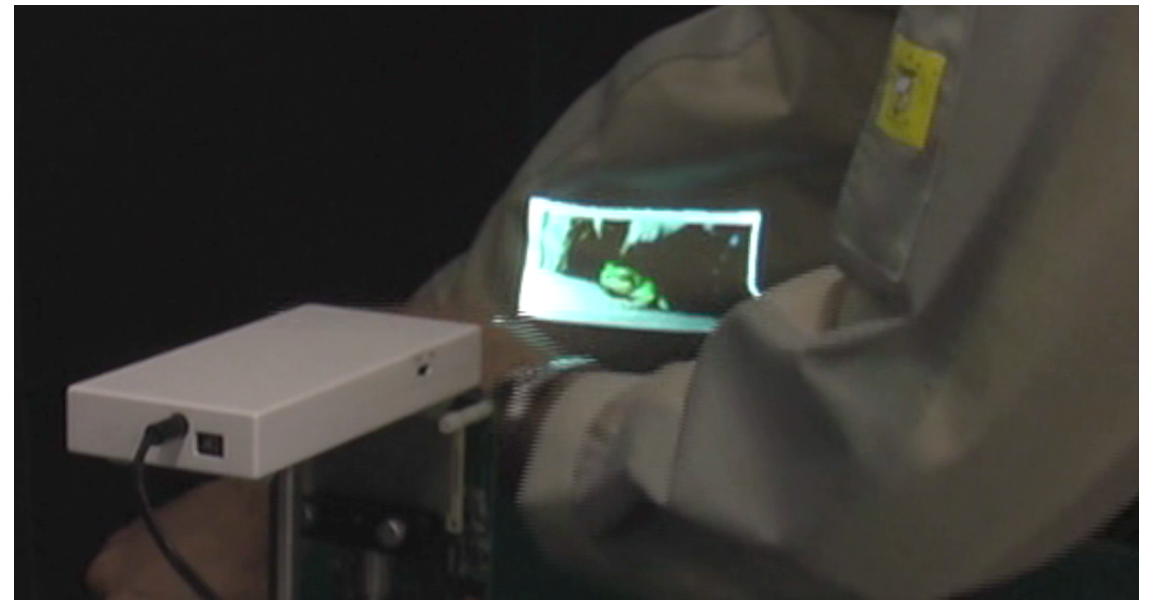
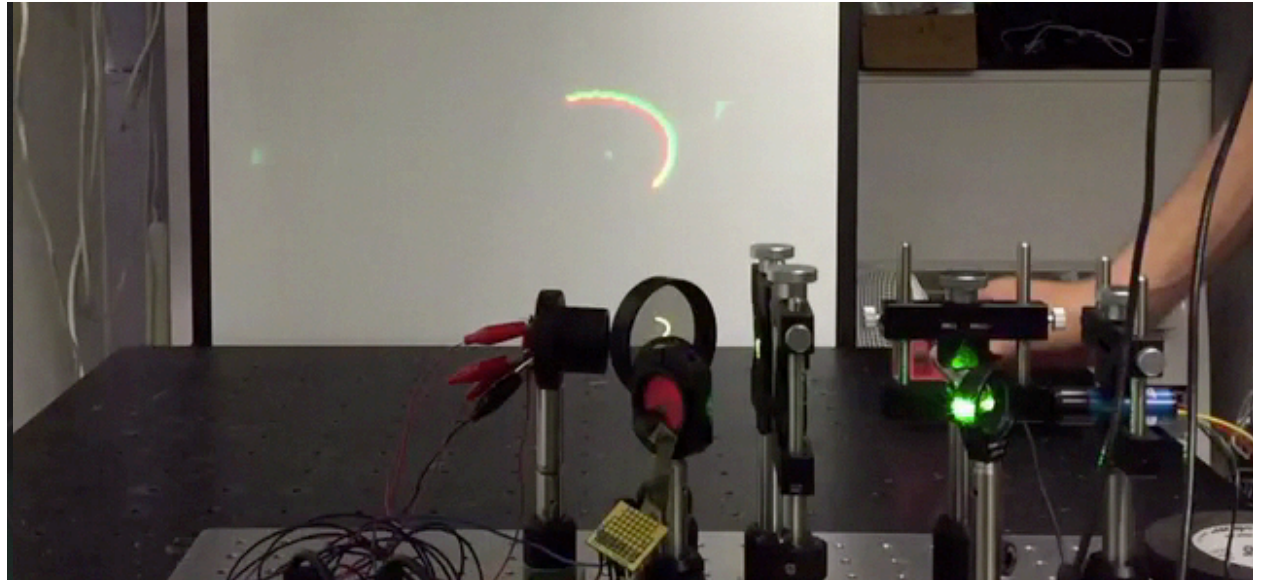
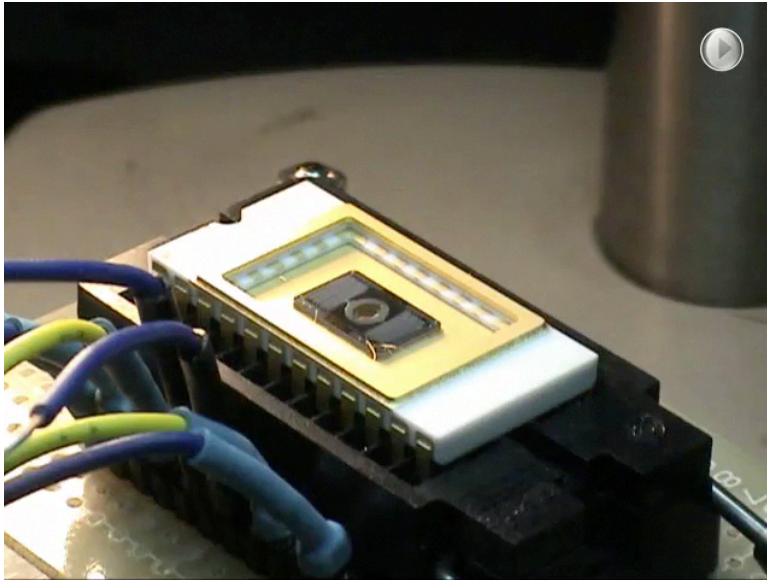
K. Takahashi, IIS, Univ. of Tokyo 2005



T. Takahashi, IIS, Univ. of Tokyo 2006

MEMS Actuators for Optical Applications

Interactive Image Displays

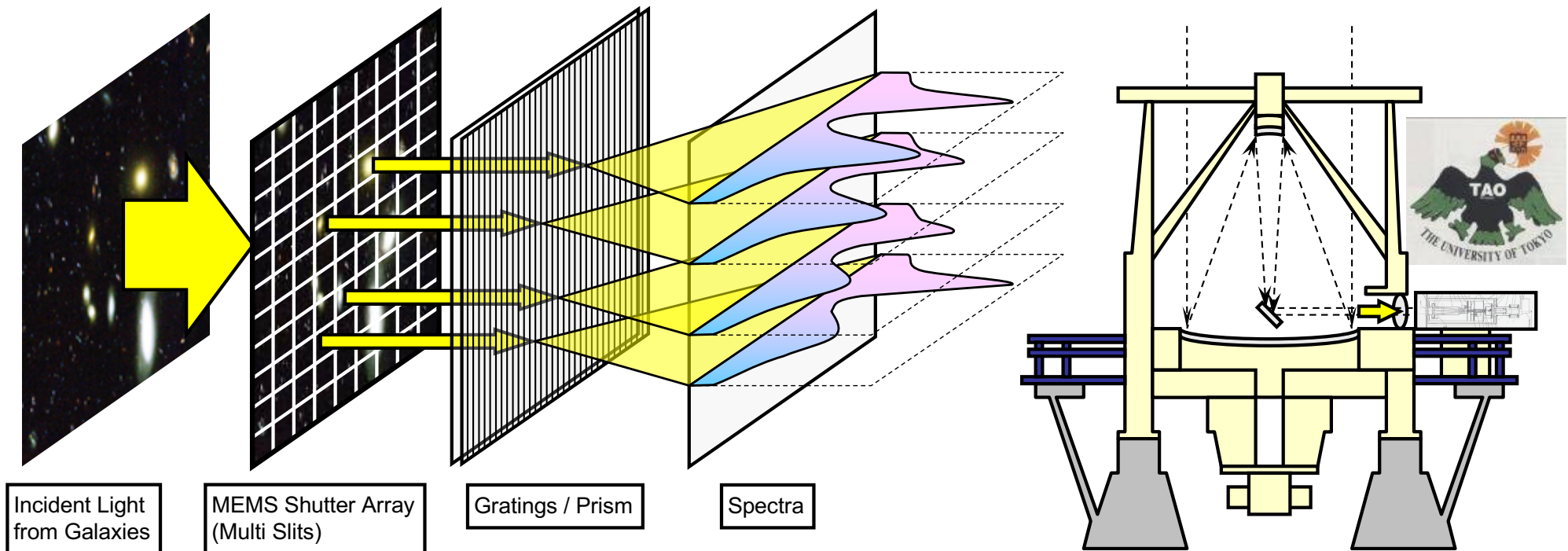
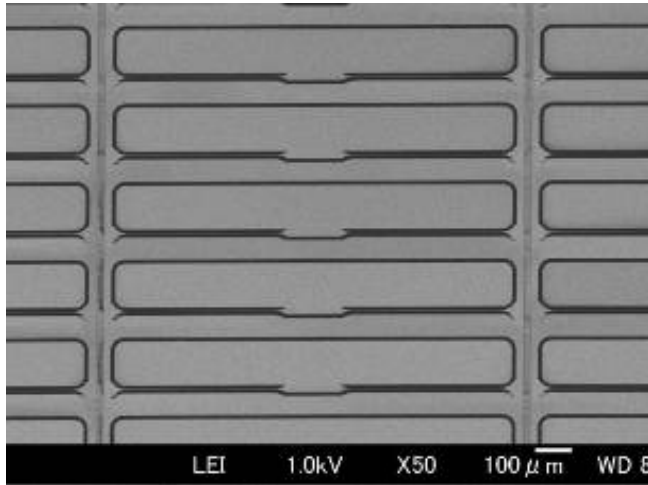


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5. Faster !
6. Summary

Multi-Slit Array for Observatory

TAO in Atacama (5639 m)



HIGH CONTRAST, CRYOGENIC, LARGE MICROMIRROR ARRAY FOR MULTI-OBJECT SPECTROSCOPY

Frederic Zamkotsian¹, Michael Canonica^{2,3}, Patrick Lanzoni¹, Wilfried Noell²

¹ Laboratoire d'Astrophysique de Marseille - CNRS, Marseille, France

² Ecole Polytechnique Fédérale de Lausanne, Neuchâtel, Switzerland

³ MIT, Cambridge, USA

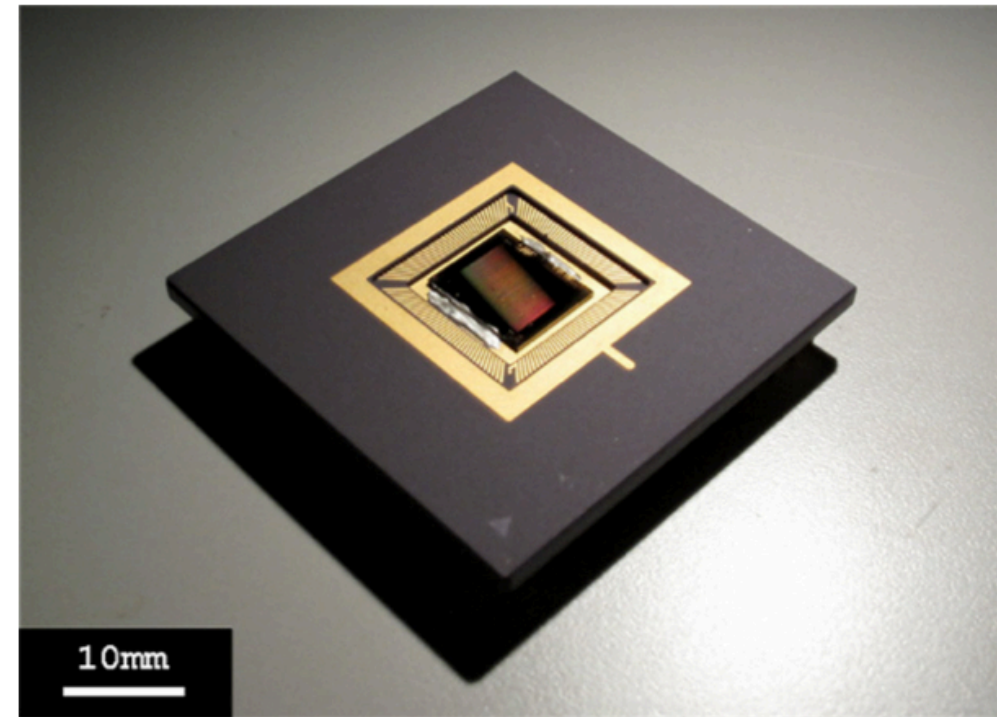
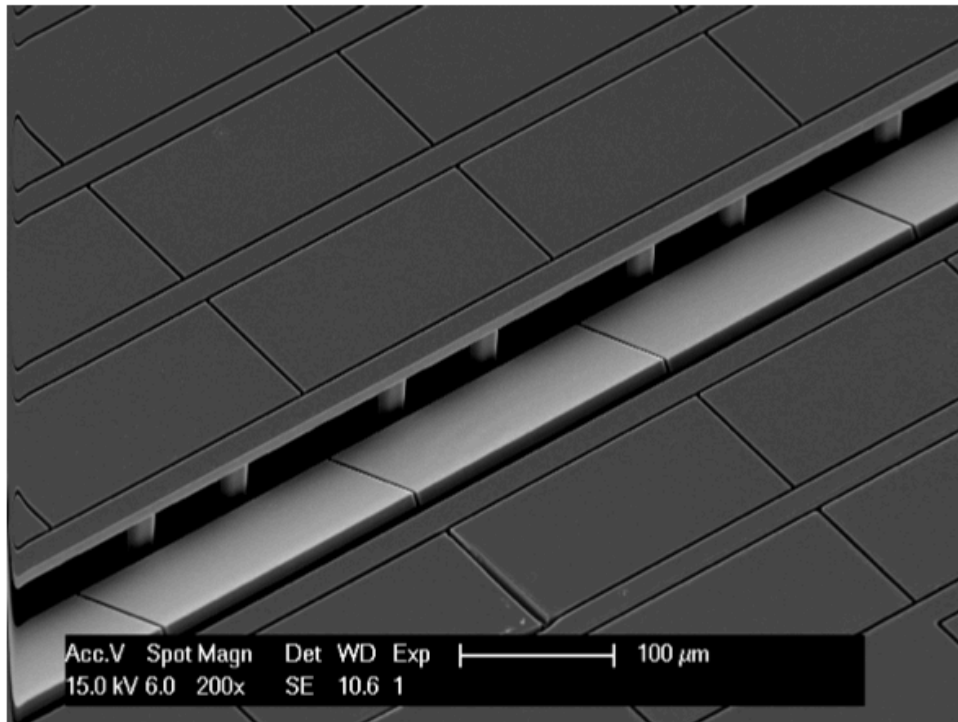
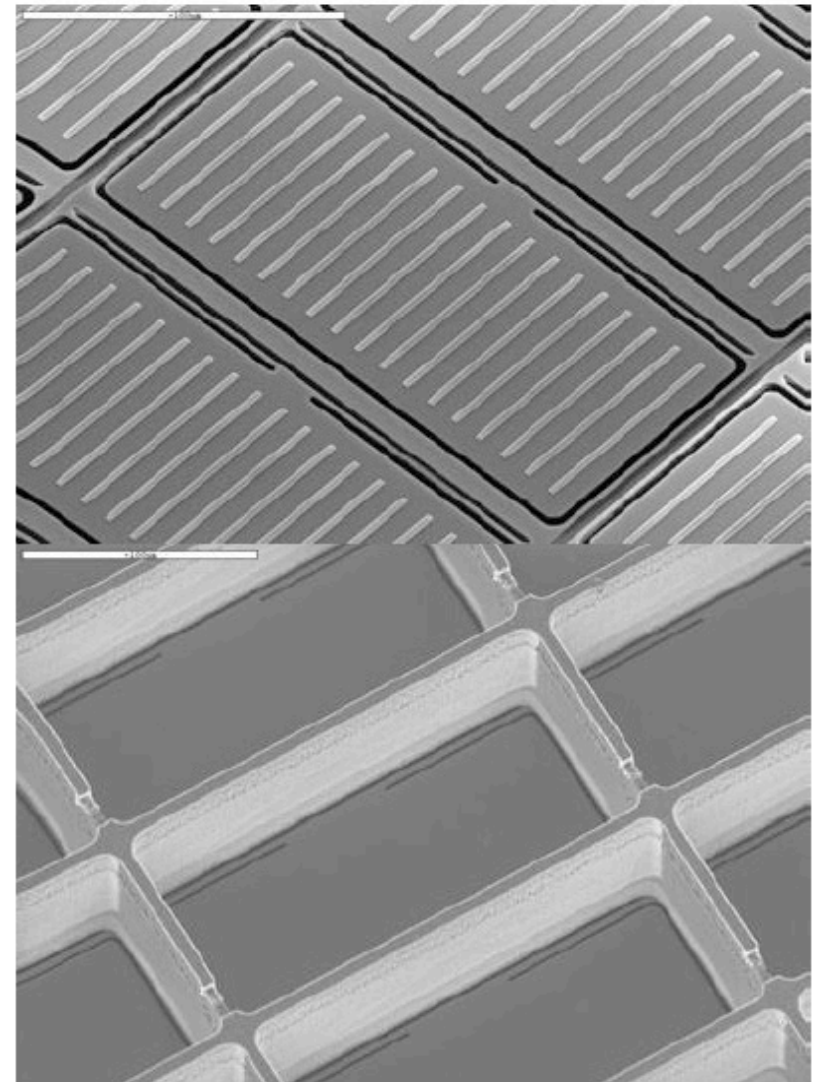
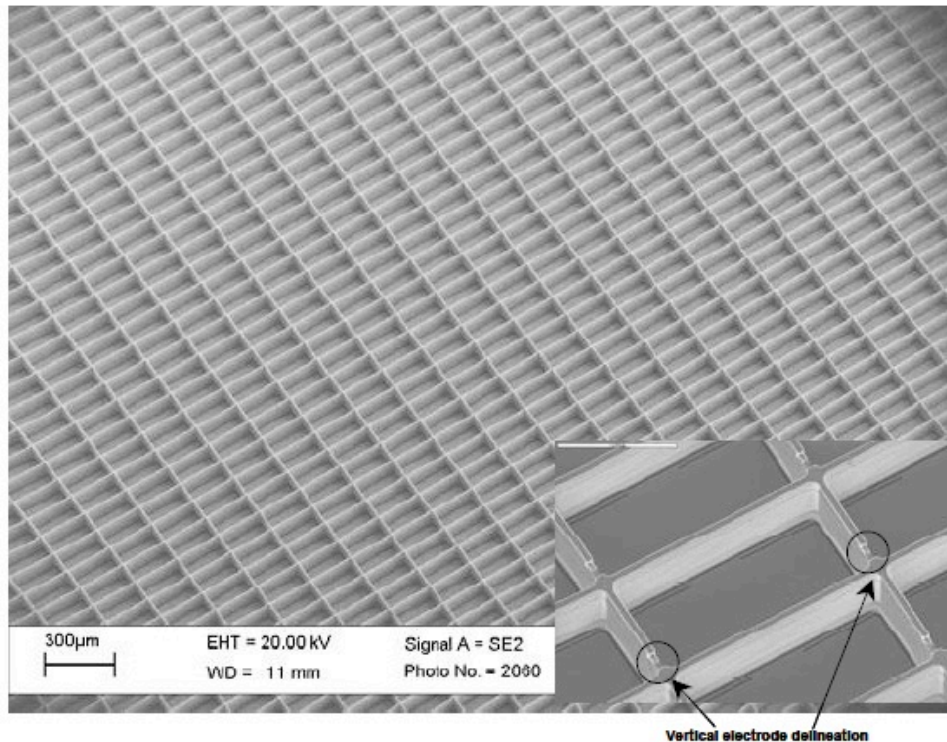


Figure 1. 64 x 32 micromirror array with high fill factor in one direction, providing long slits. Each mirror measures 200 x 100 μm^2 . Array surface picture and packaged device.

Electromagnetic MEMS Shutter for NASA JWST

Li et al., "Microshutter array development for the James Webb space telescope," (2005) SPIE 5650 9

- For satellite mount
- **Open Electromagnetically**
- **Latch Electrostatically**
- Matrix 64×128
- Size $100 \mu\text{m} \times 200 \mu\text{m}$

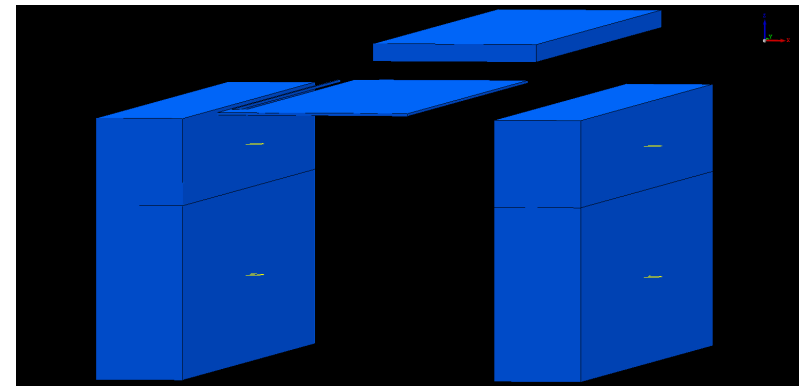
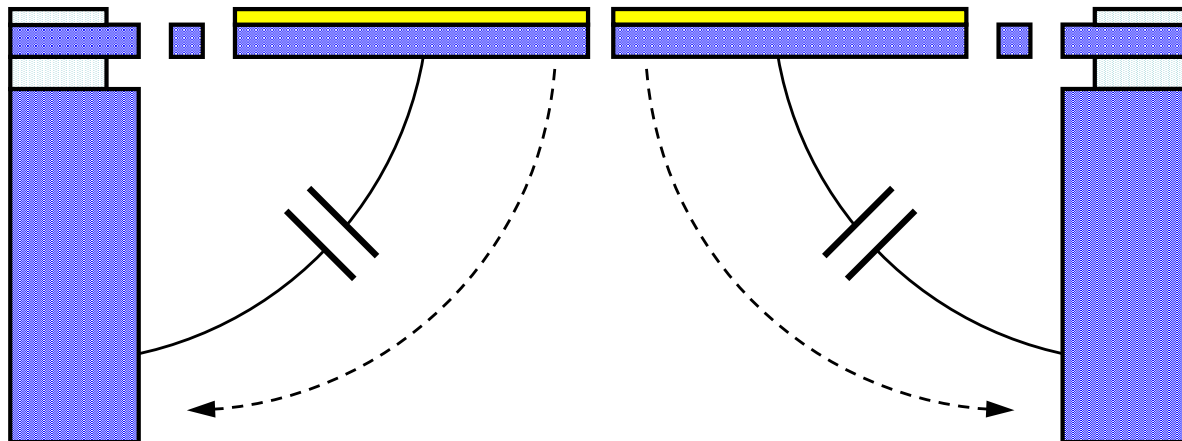
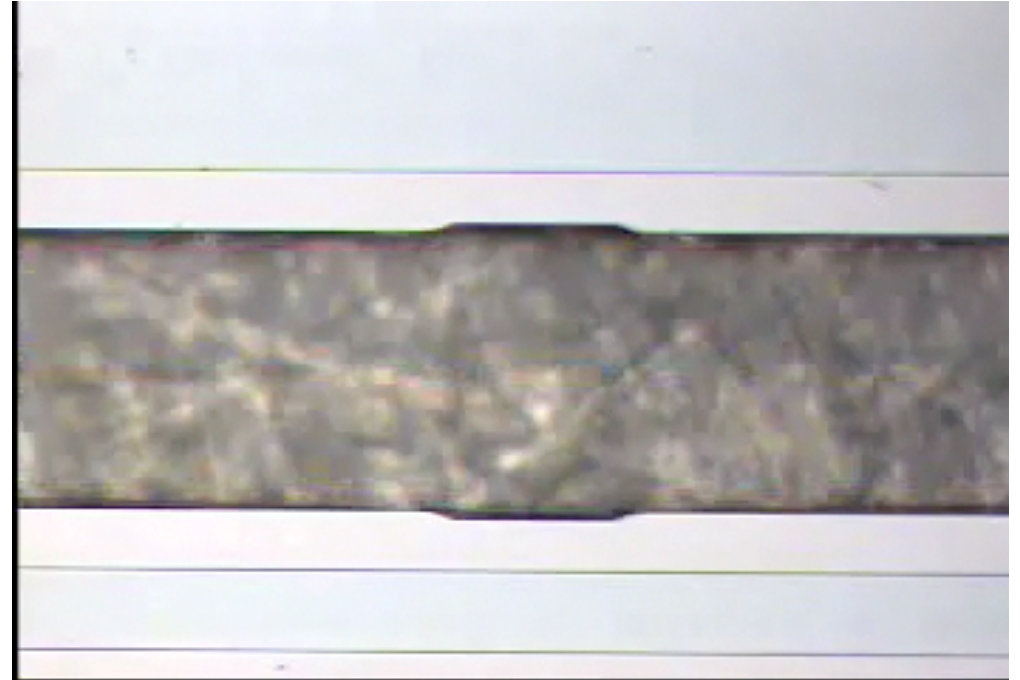
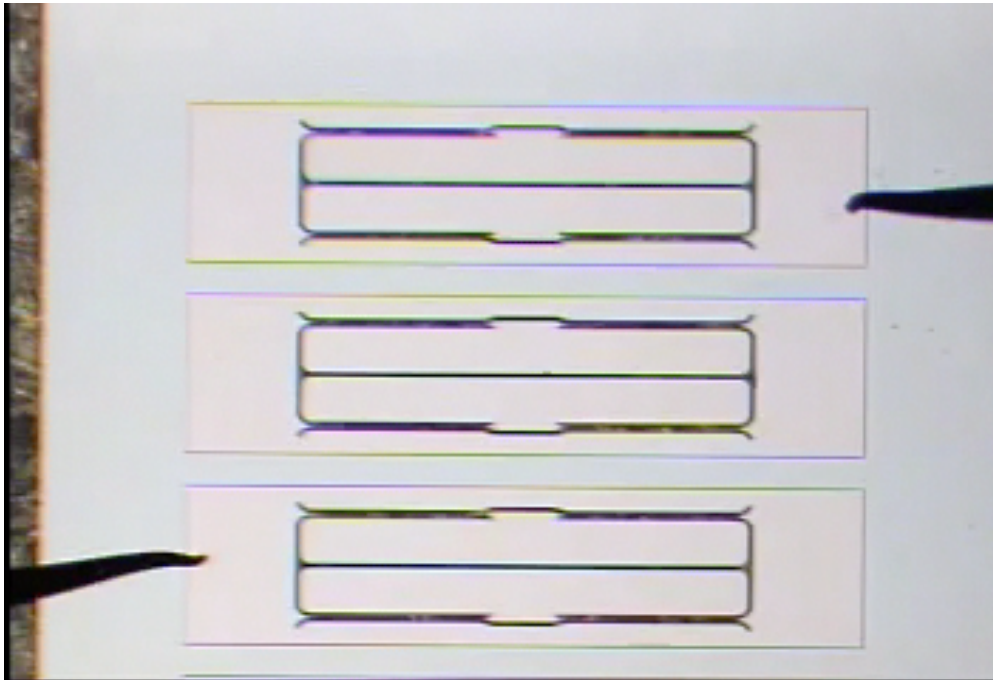


単位面積あたり発生力

	静電駆動	電磁駆動	圧電駆動 (磁歪・電歪駆動)	熱膨張 (通電加熱)
原理図				
単位面積あたりの発生力 (N/m ²)	$(1/2) \epsilon_0 E^2$ E : 電場 ϵ_0 : 誘電率	IB / w I : 駆動電流 B : 磁束密度 w : 線幅	$E \epsilon$ E : ヤング率 ϵ : 歪	$E \alpha \Delta T$ E : ヤング率 α : 線膨張系数 ΔT : 温度変化
	$10^1 \sim 10^4$ N/m ²	$10^1 \sim 10^3$ N/m ²	圧電 $10^7 \sim 10^8$ N/m ² 電歪 $10^7 \sim 10^9$ N/m ²	$10^6 \sim 10^8$ N/m ²
代表的設計値	静電ギャップ $g = 1 \sim 10 \mu\text{m}$ 駆動電圧 $V = 1 \sim 100$ V	永久磁石 $H_c \sim 10$ kOe 駆動電流 $I = 1$ mA \sim 1 A 配線幅 $w \sim 10 \mu\text{m}$	ヤング率 $E \sim 100$ GPa 圧電の機械歪 $\epsilon = 0.01 \sim 0.1$ % 磁歪、電歪の機械歪 $\epsilon = 0.01 \sim 1$ %	ヤング率 $E \sim 100$ GPa 線膨張系数 $\alpha \sim 10$ ppm 温度変化 $\Delta T = 1 \sim 100$ °C

Optical MEMS Shutter Array at UTokyo

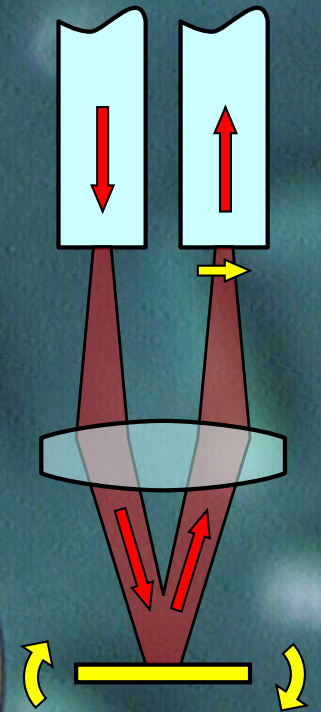
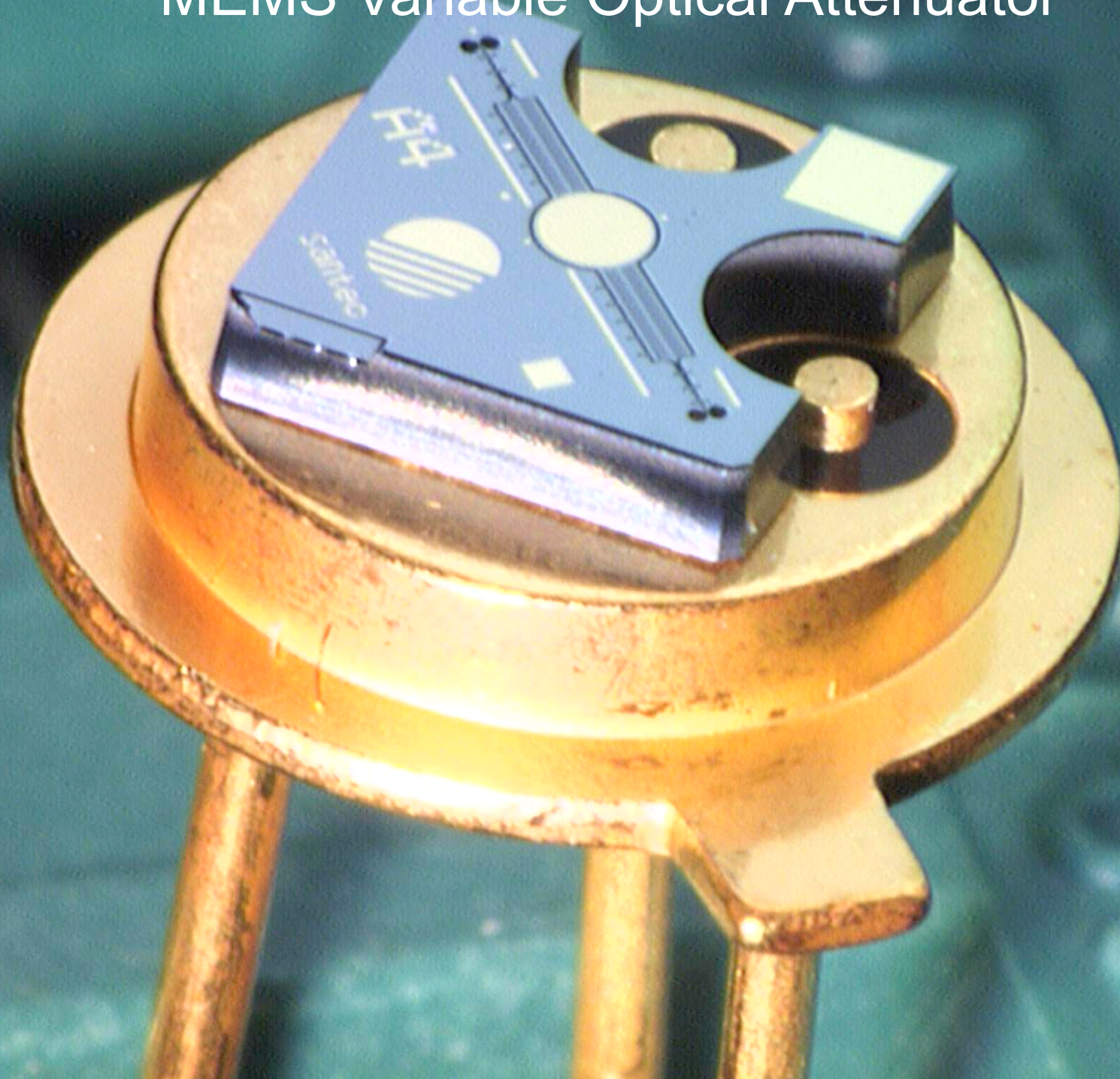
W 100 μm x L 1000 μm



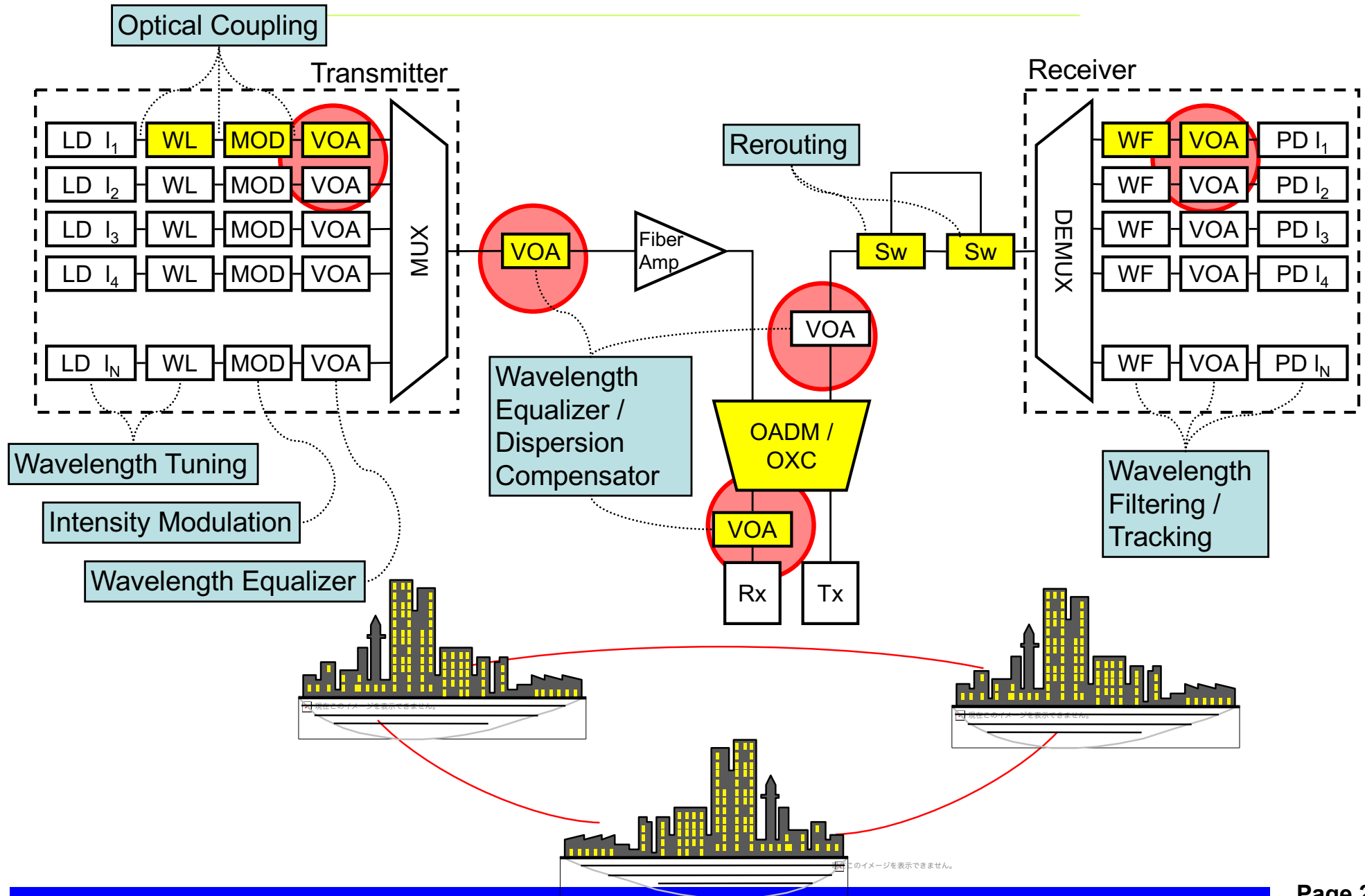
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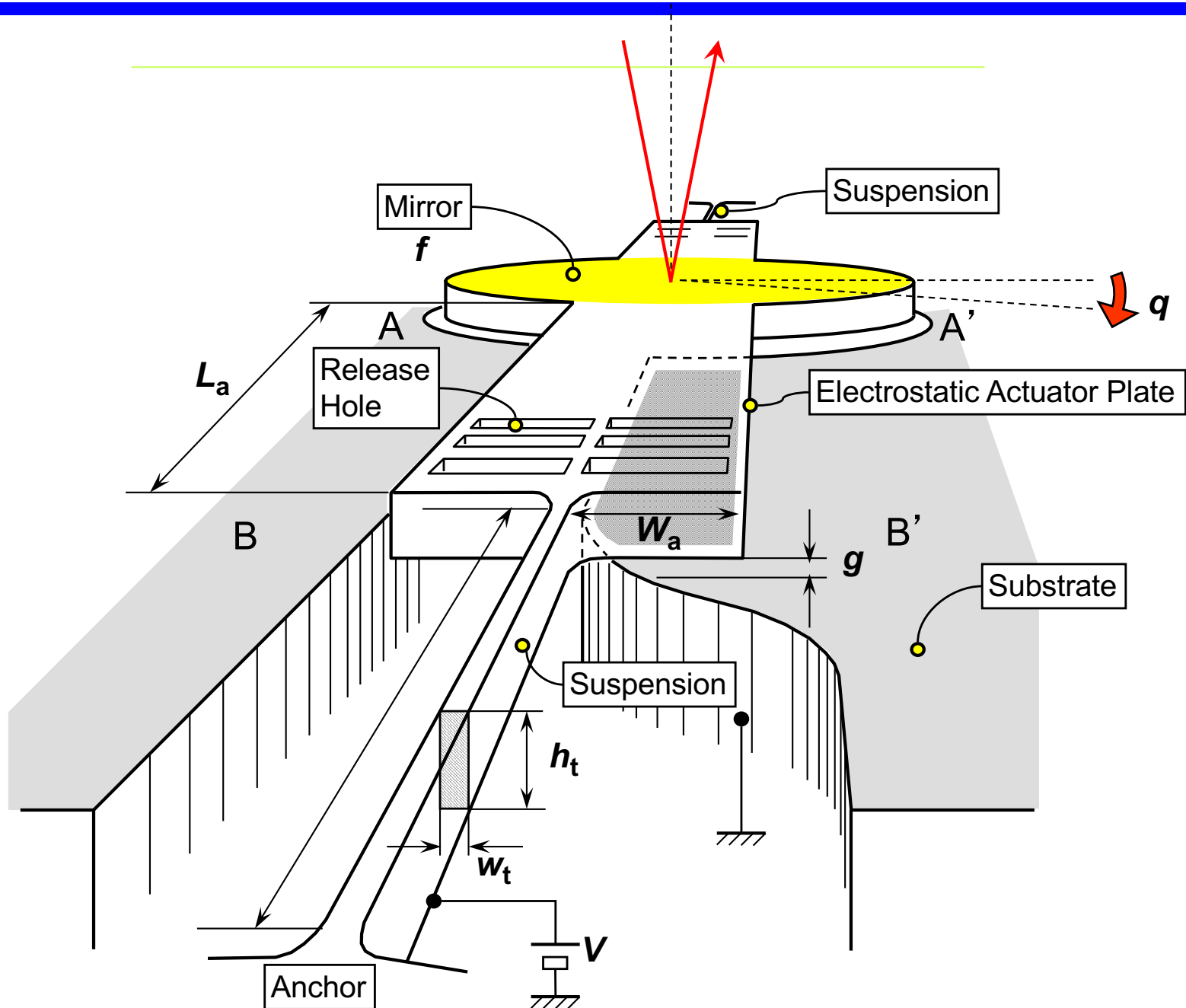
MEMS Variable Optical Attenuator



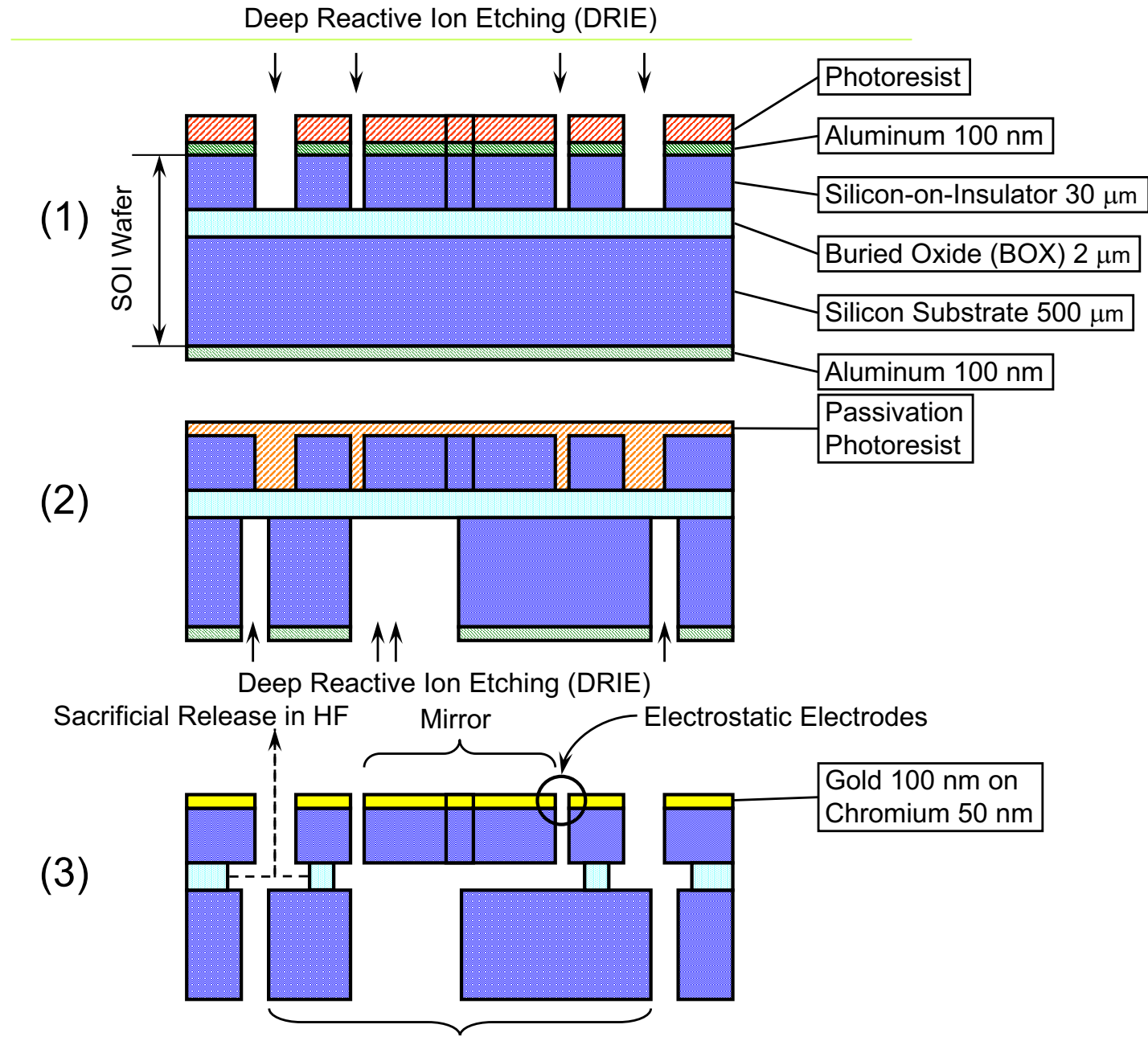
MEMS VOA Application in Fiber Telecom Network



Simple Structures and Process for VOA

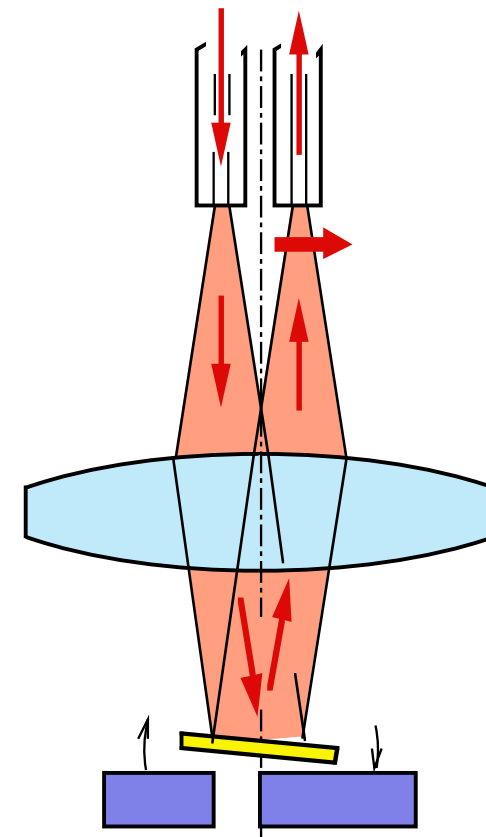
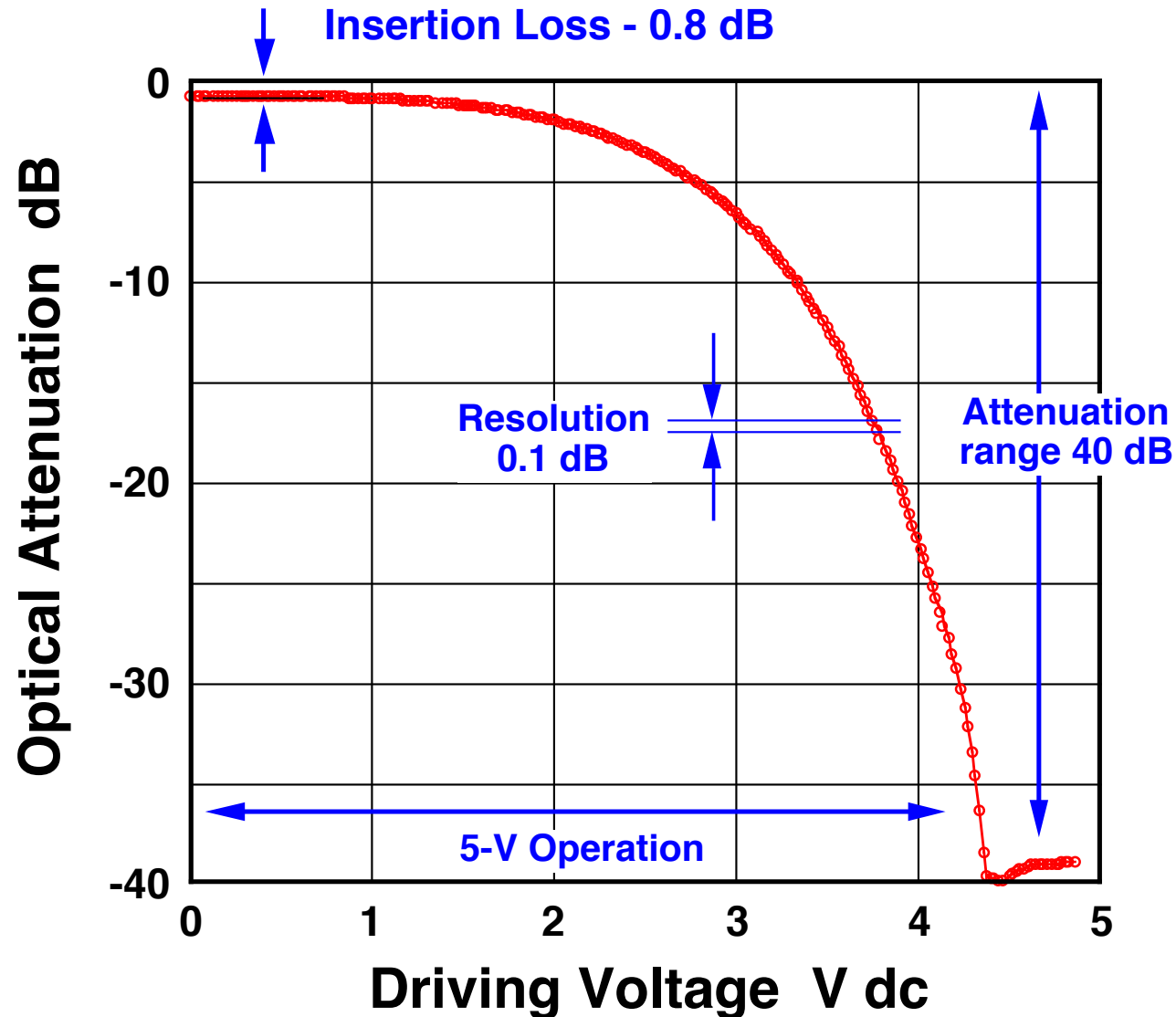


SOI Bulk Micromachining by DRIE



Attenuation Control and Complete Block-out

Normally-Bright Mode

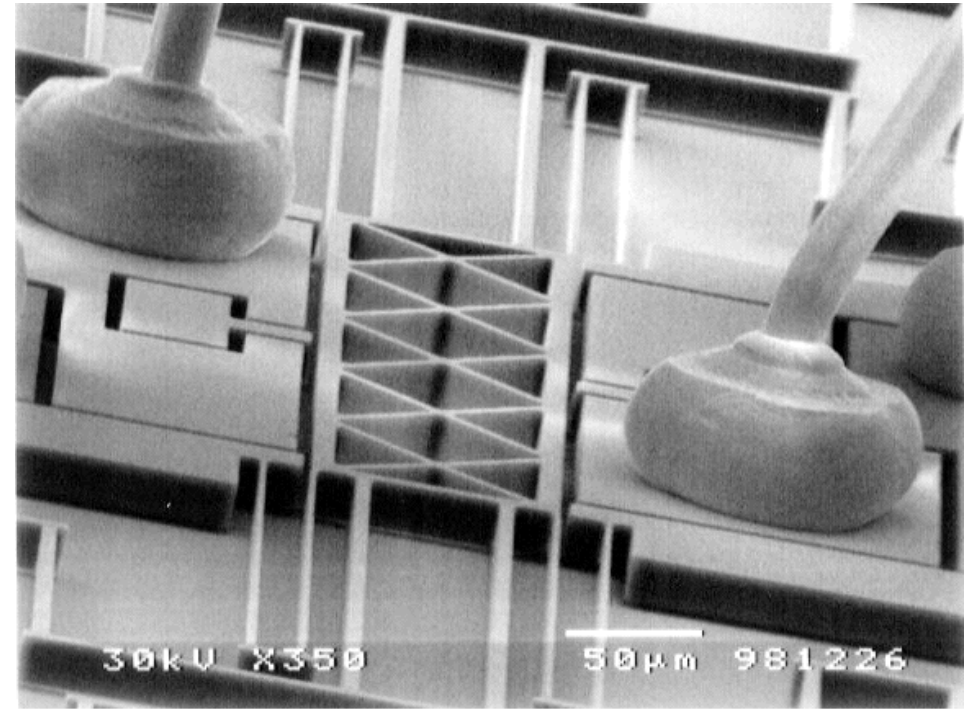
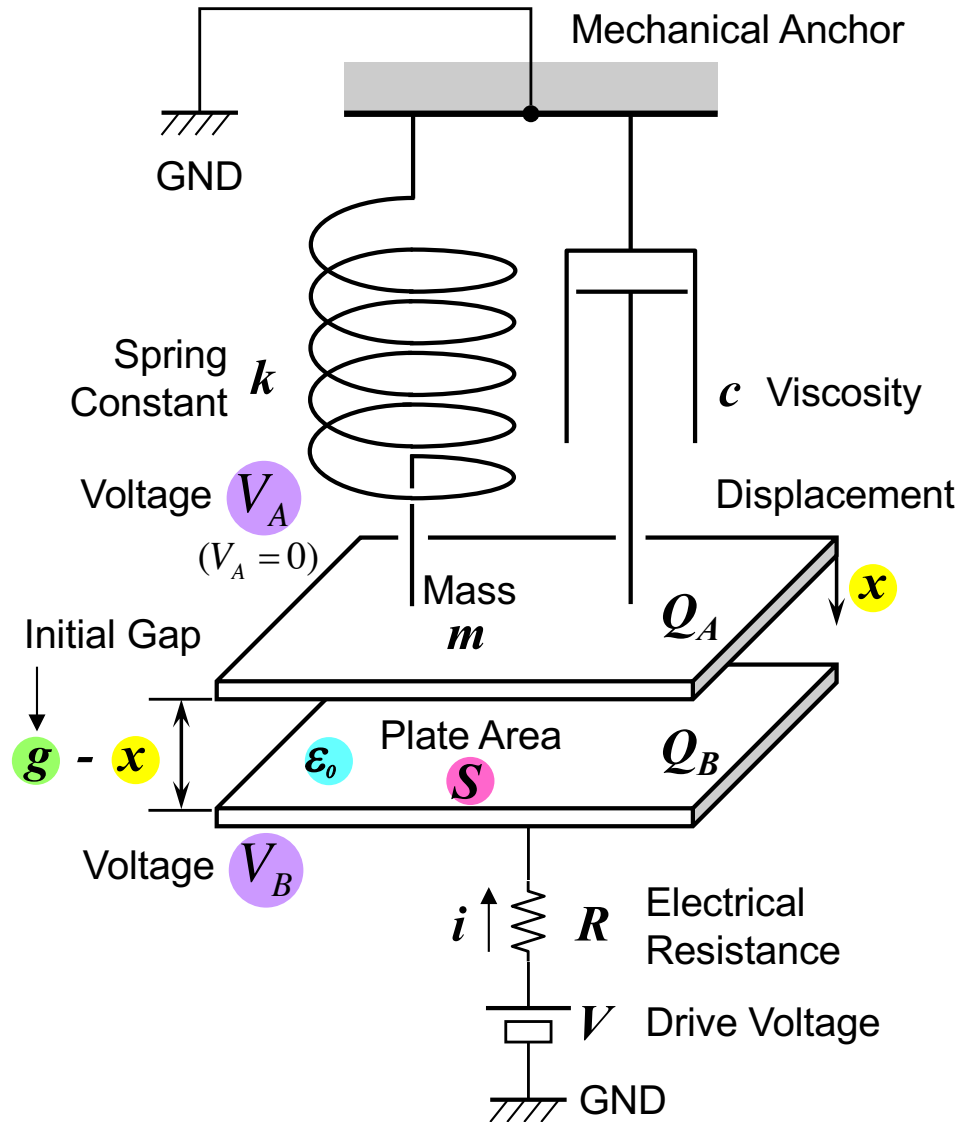


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静電駆動マイクロアクチュエータ

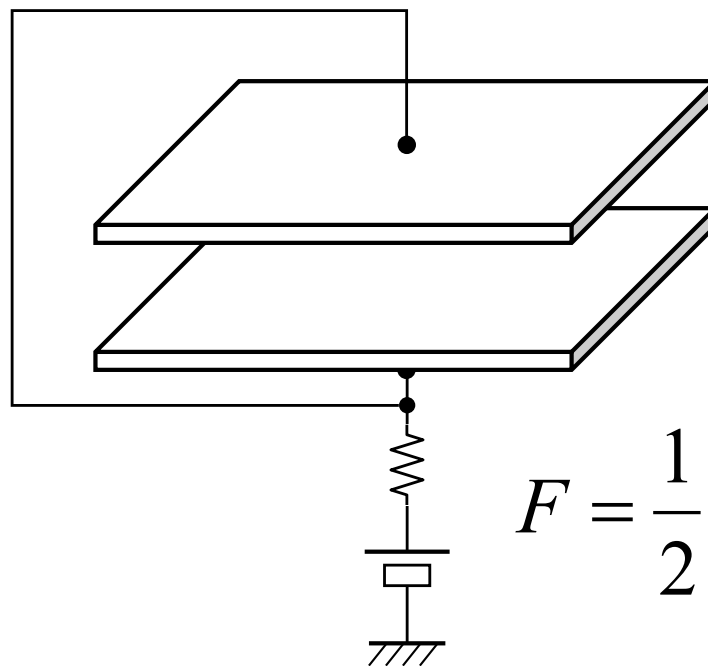
電圧印加 → 静電引力 → 機械的変形



Electrostatic micro actuator (bi-directional)

$$F = \frac{1}{2} \epsilon_0 \frac{S}{(g-x)^2} (V_A - V_B)^2$$

第1問 電極間を接続するとどうなるでしょう？



$$F = \frac{1}{2} \epsilon_0 \frac{S}{(g-x)^2} (V_A - V_B)^2$$

A
動く

B
動かない

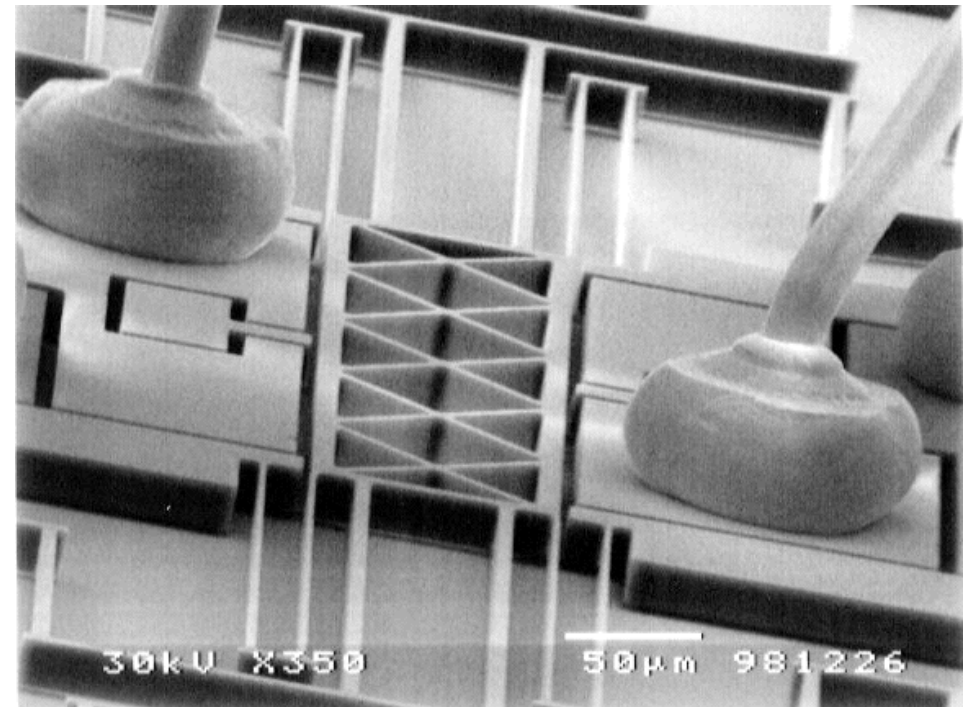
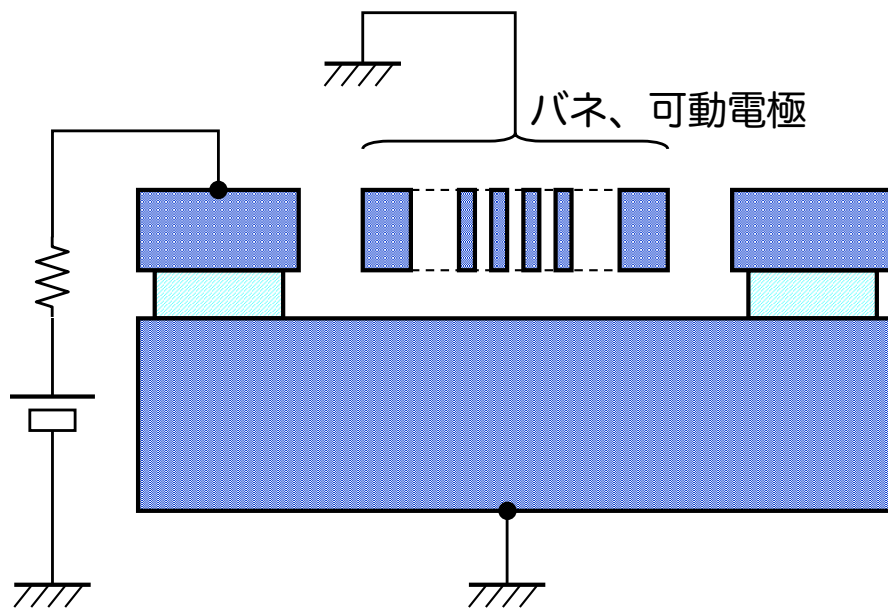
正解と解説

B
動かない

電極間が等電位であれば、静電引力は発生しない。
→よって、等電位の電極どうしは動かない。

この原理の応用例：

可動構造と基板を等電位に接地して、下向きの動きを防止。

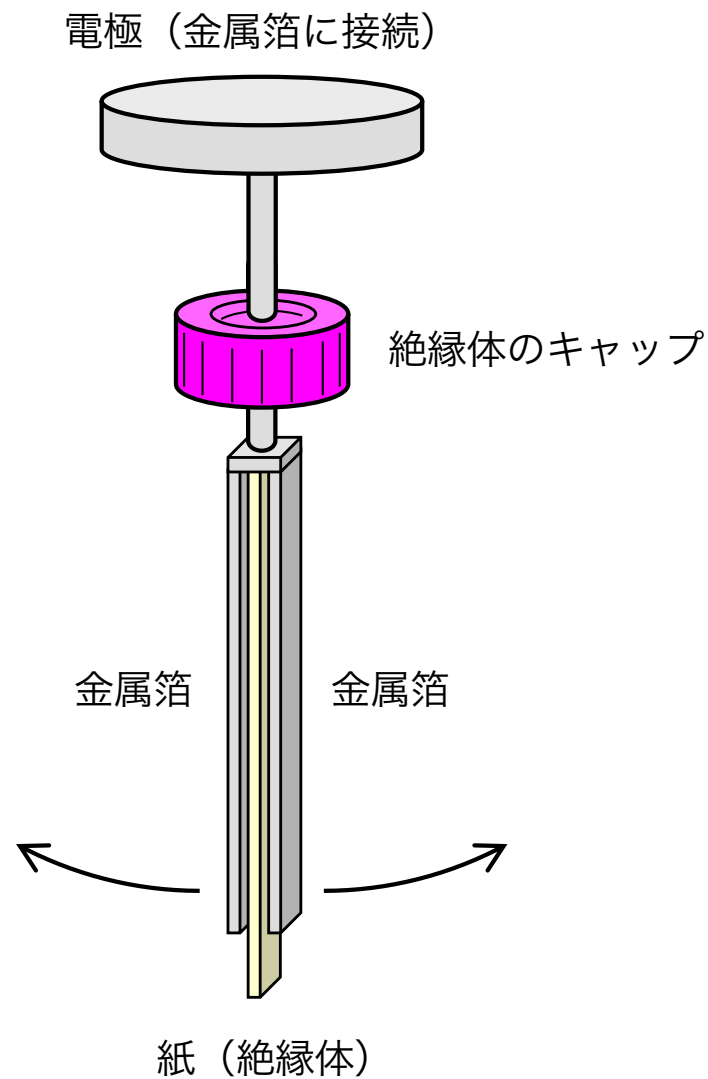


第2問 等電位なのに、なぜ動くのでしょうか？

箔（はく）検電器



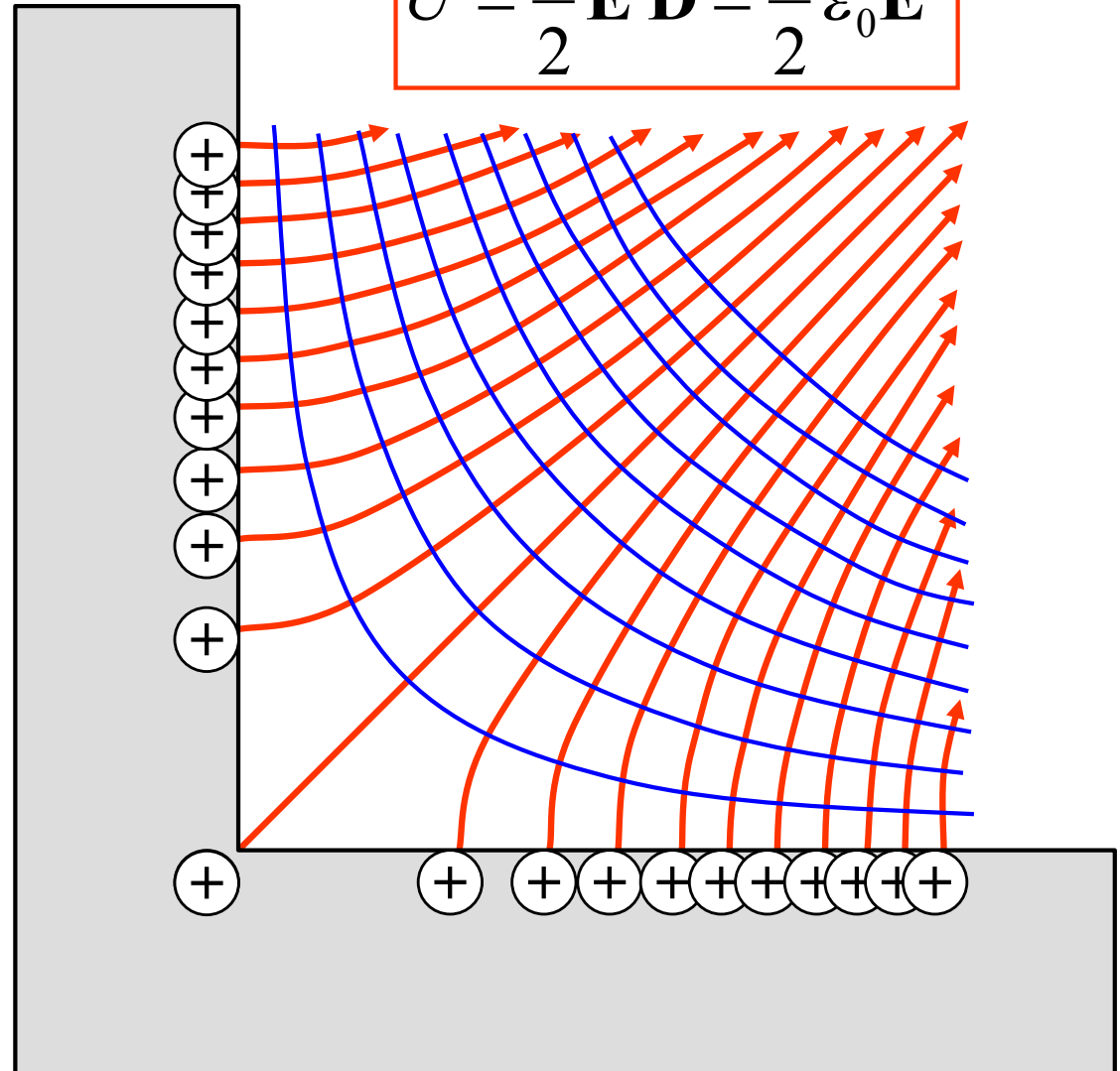
<http://www.kenis.co.jp/>



解説

等電位であっても、クーロン反発力は働きます

$$U = \frac{1}{2} \mathbf{E} \mathbf{D} = \frac{1}{2} \epsilon_0 \mathbf{E}^2$$



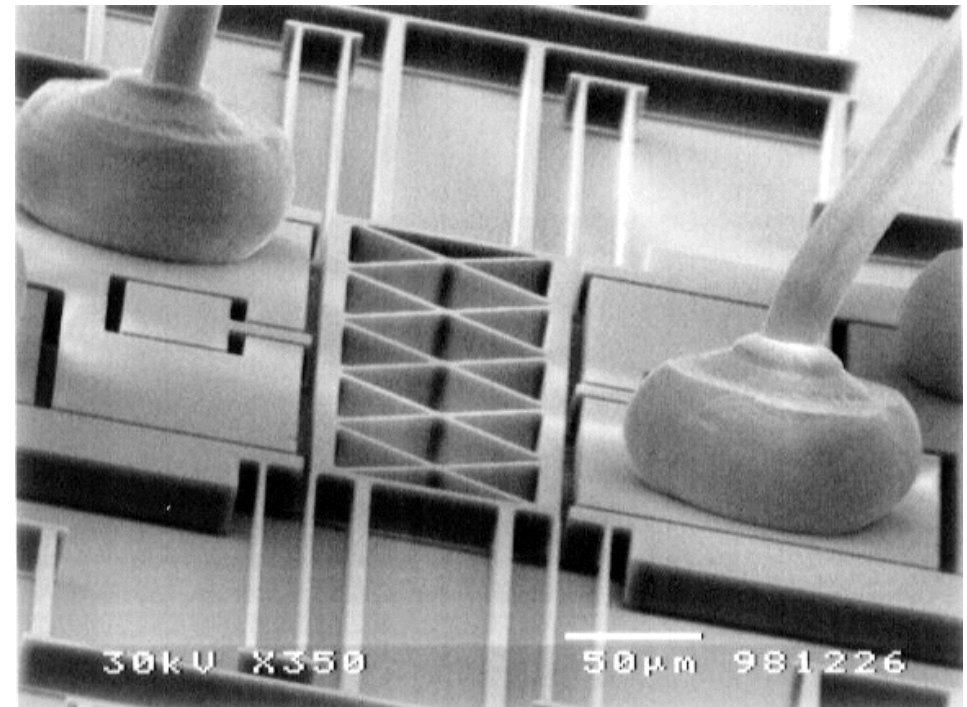
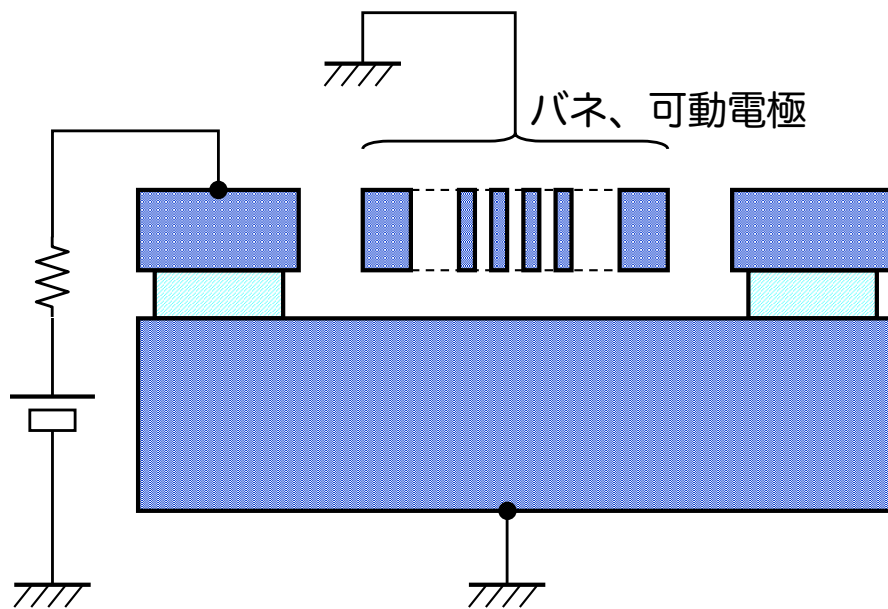
<http://www.kenis.co.jp/>

だまされてませんか？

B
動かない

電極間が等電位であれば、静電**引力**は発生しない。
→よって、等電位の電極どうしは動かない。

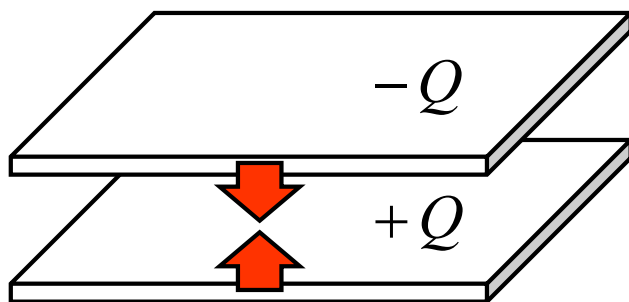
ただし、等電位であっても静電反発力は働く。



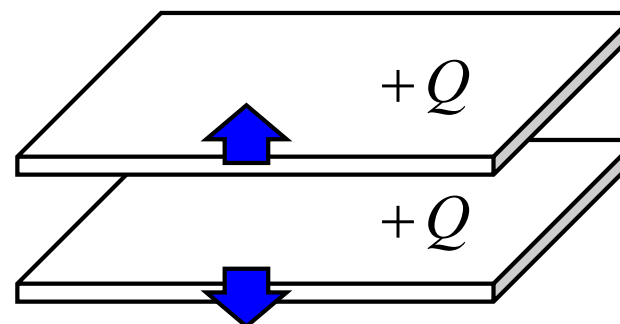
第3問 静電反発力を使わない理由は？

どっちもクーロン力、電荷の量は同じ、符号が違うだけ

$$F = \frac{1}{4\pi\epsilon_0} \cdot \frac{Q_1 \cdot Q_2}{r^2}$$



静電引力アクチュエータ

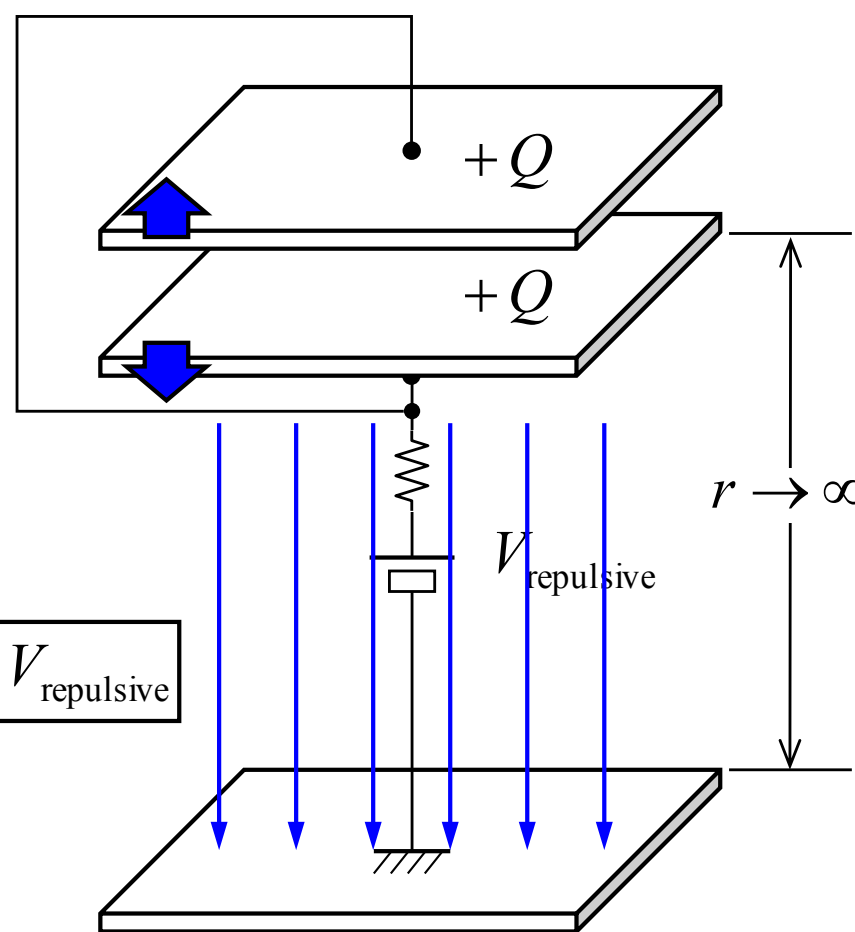
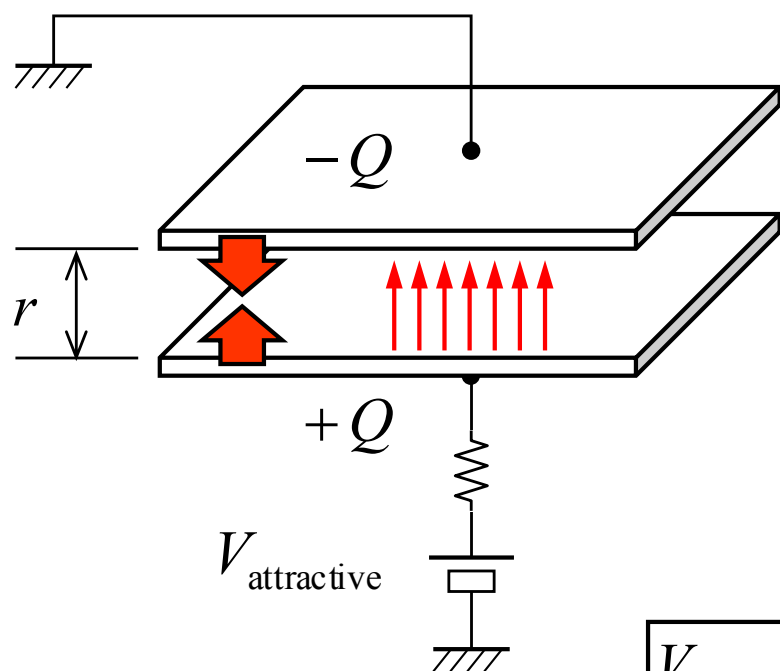


静電反発力アクチュエータ

解説 駆動電圧が高いのは損

電場に逆らって電荷を移動した仕事が「電位」

$$V = E_n \cdot r = \frac{\sigma}{2 \epsilon_0} \cdot r$$



$V_{\text{attractive}} \ll V_{\text{repulsive}}$

静電引力アクチュエータ

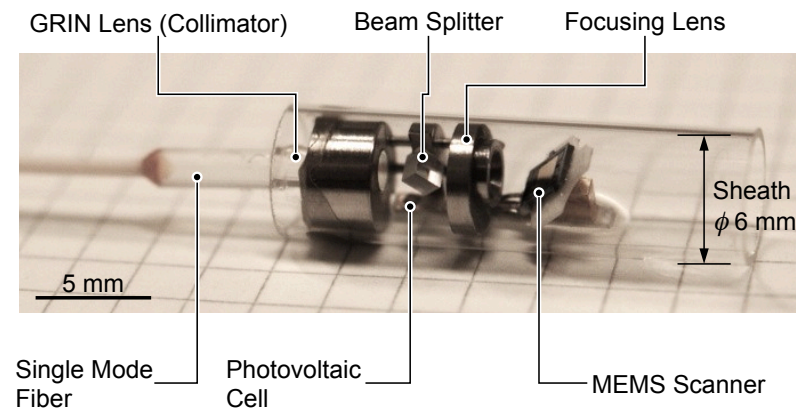
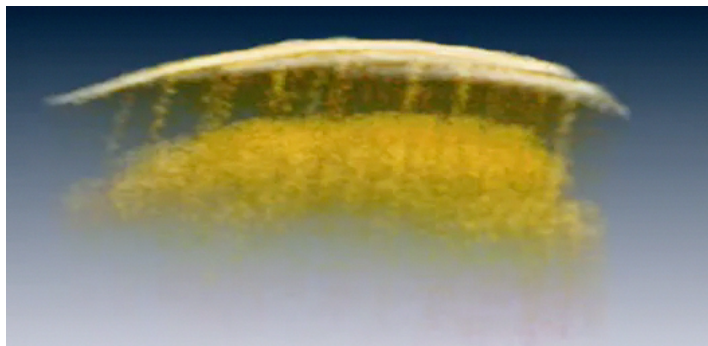
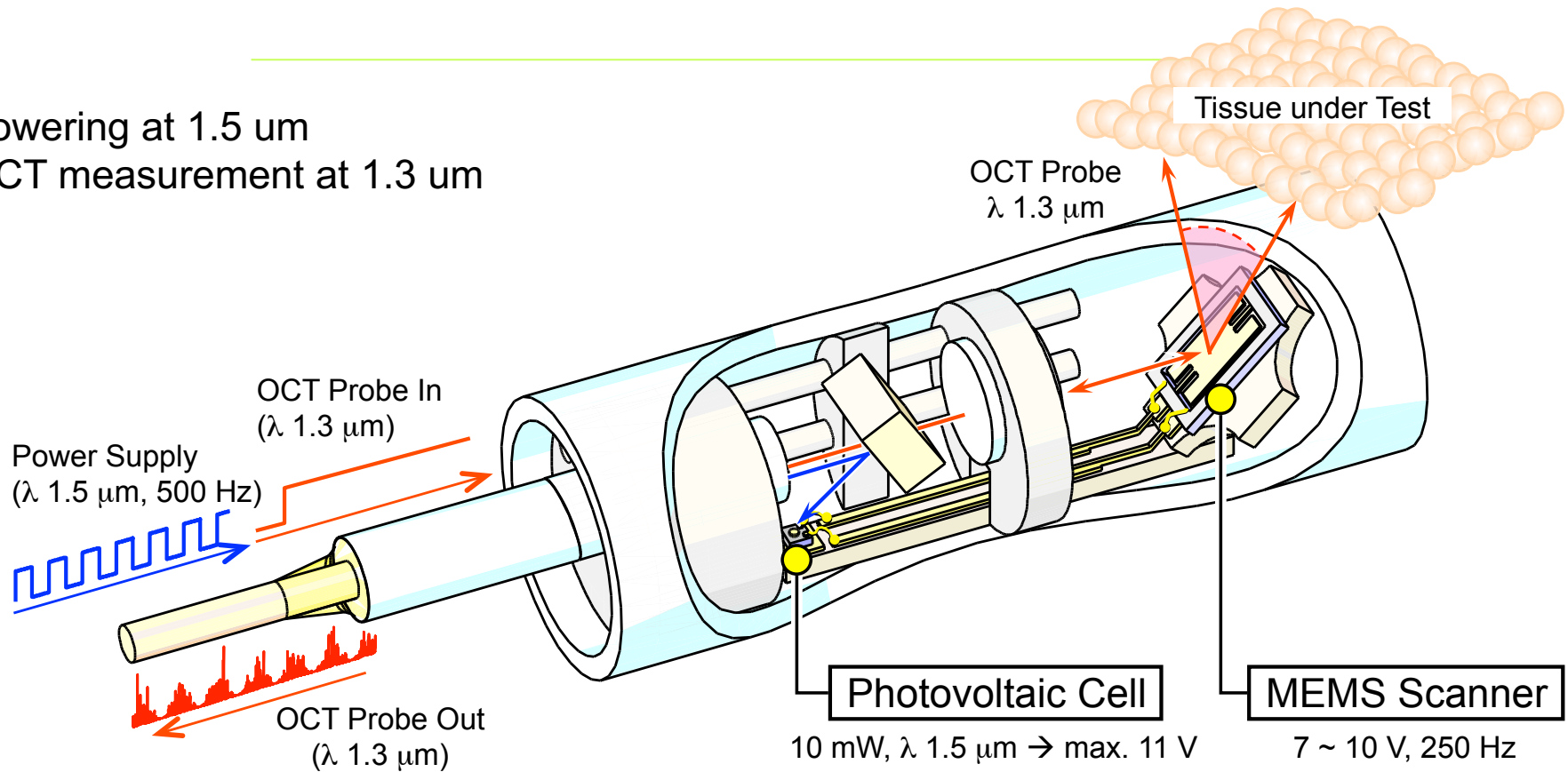
静電反発力アクチュエータ

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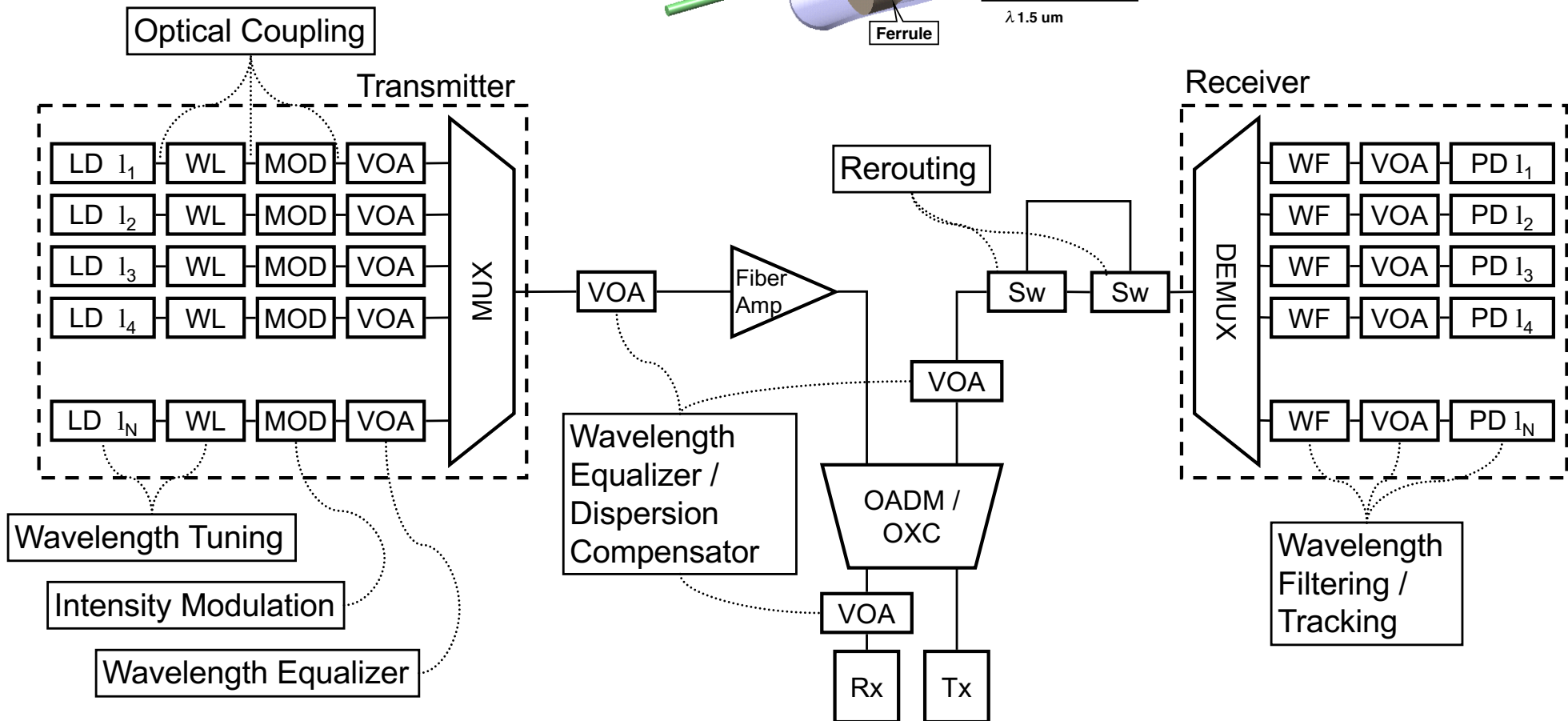
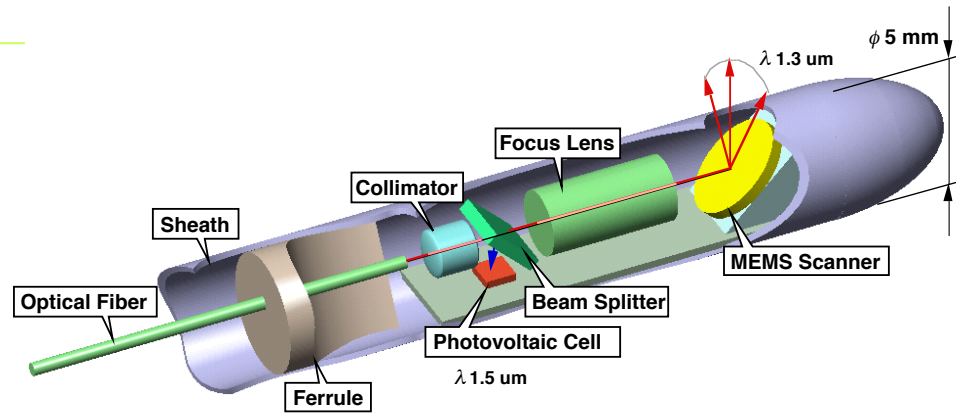
Optically Powered Fiber Endoscope

- Powering at 1.5 μm
- OCT measurement at 1.3 μm

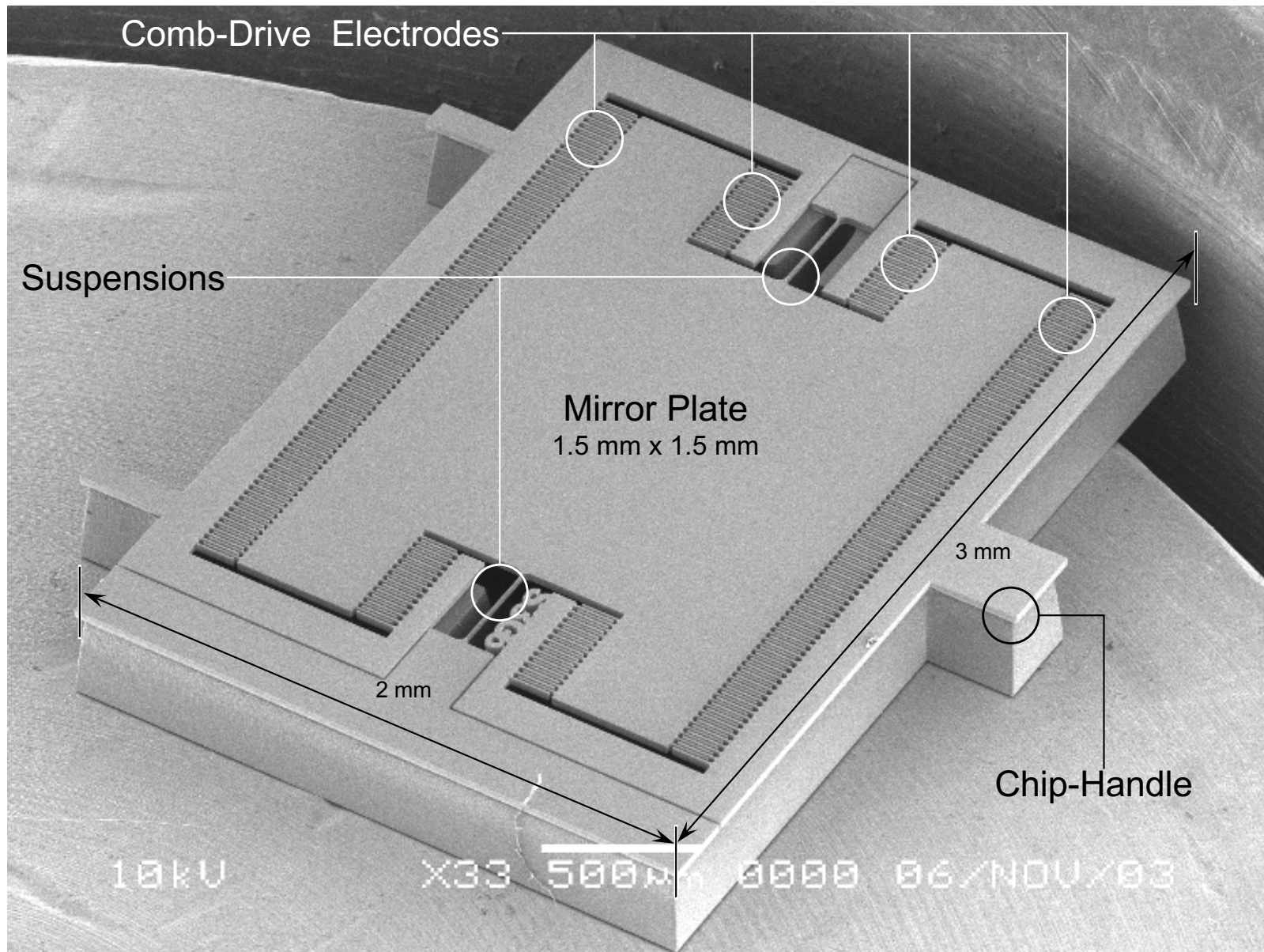


Application of WDM Technology

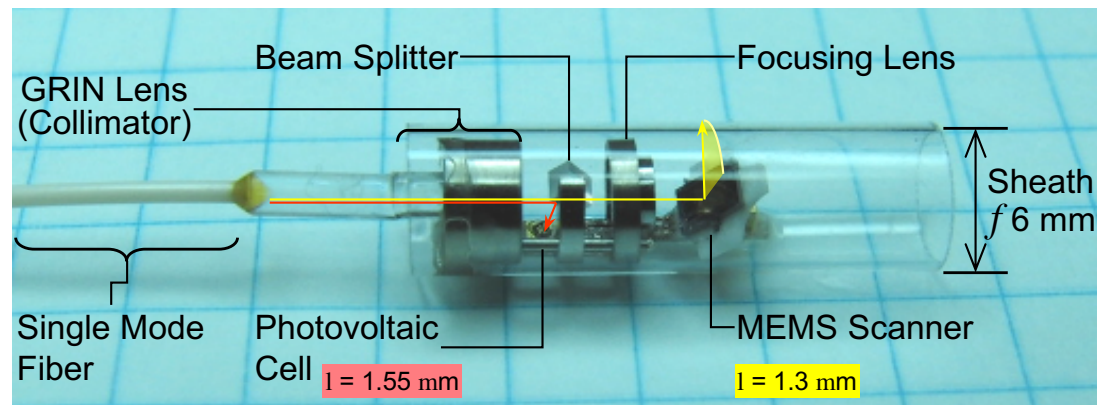
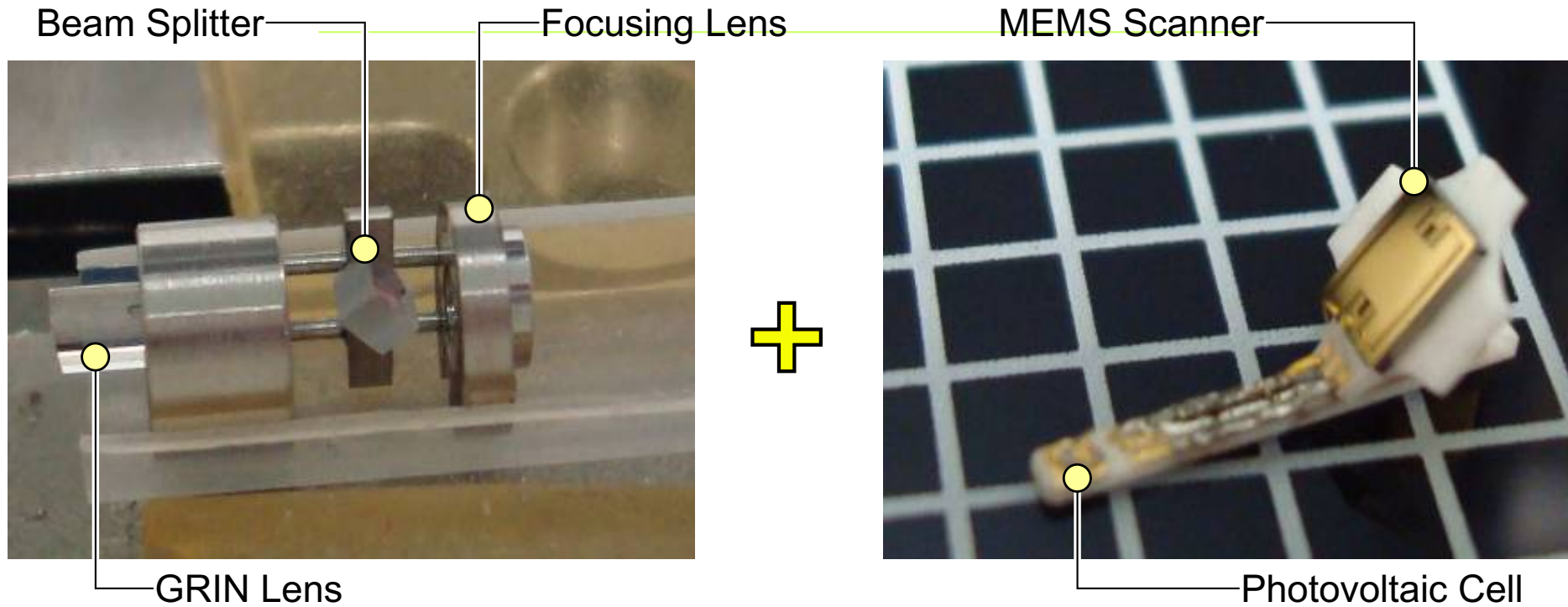
- Power 1.5 μm
- OCT Probe 1.3 μm



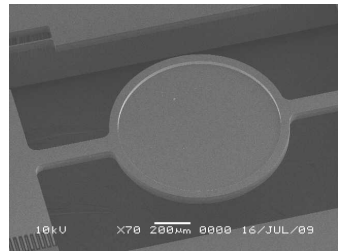
Electrostatic MEMS Optical Scanner 2 mm x 3 mm



Assembly of MEMS Endoscope Head

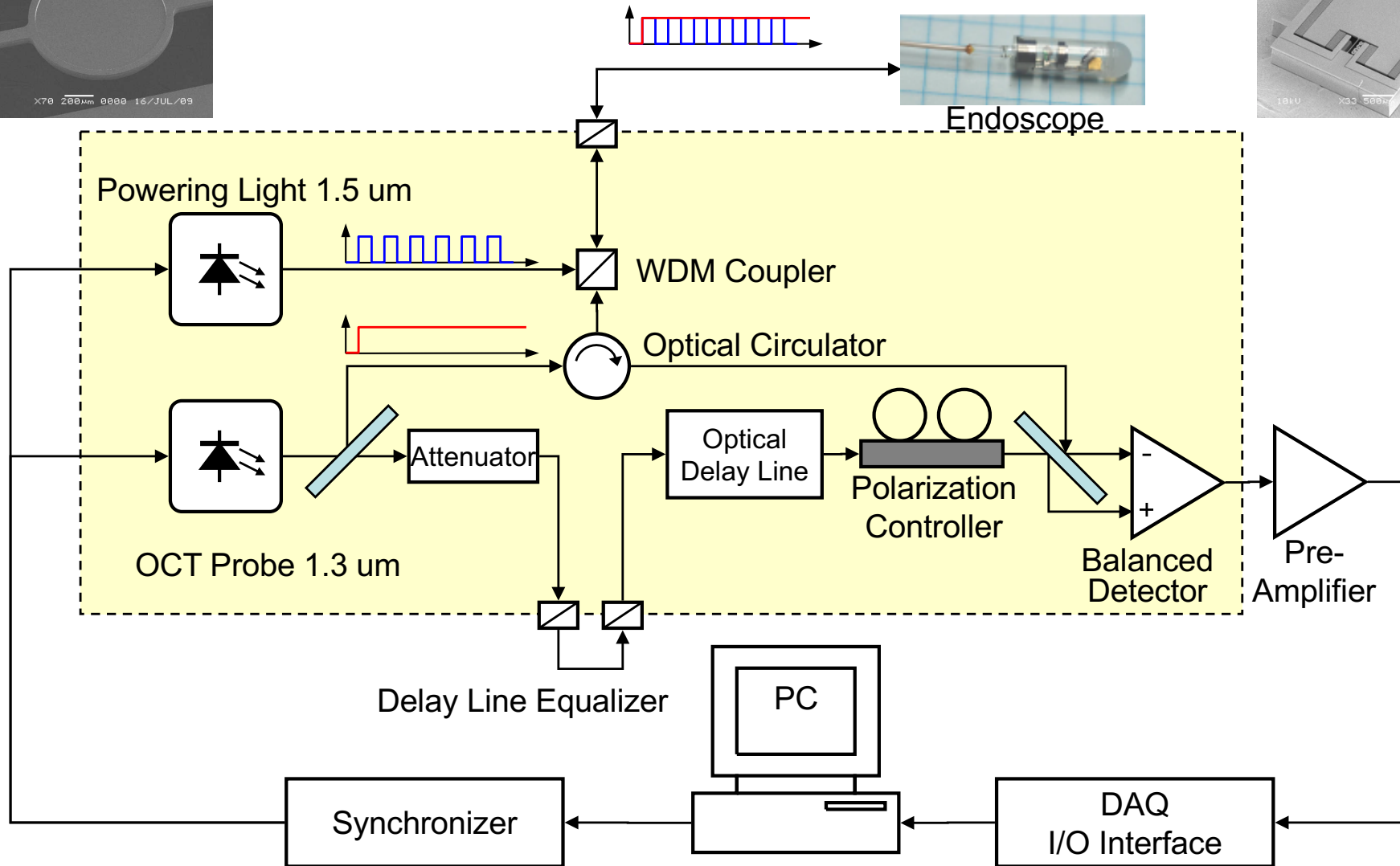
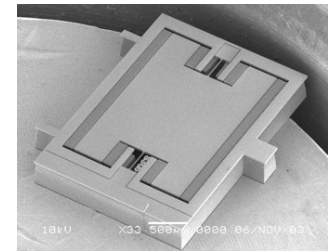


Detail View of Optically Powered OCT

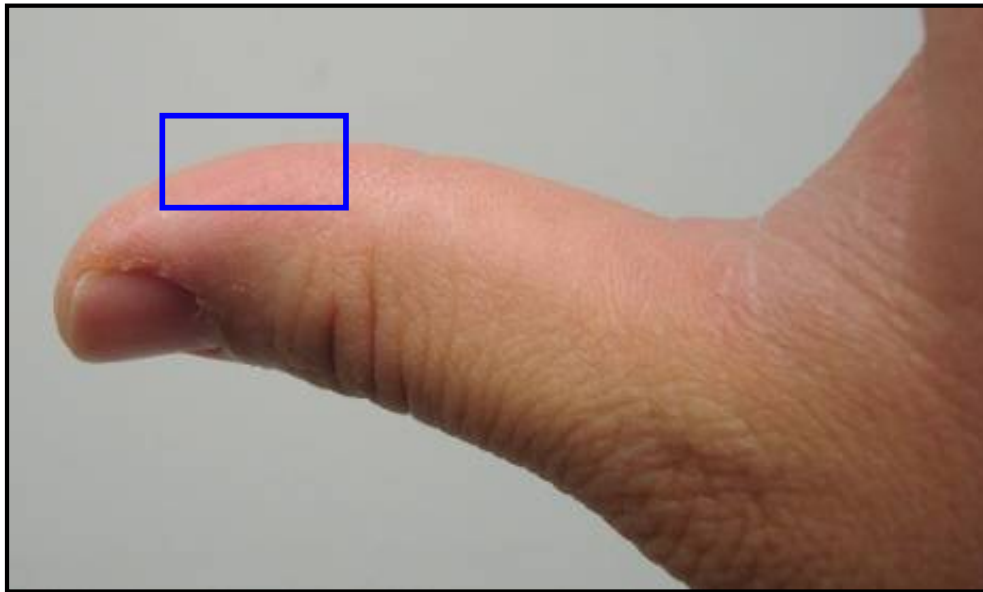


← Fast Scanner

Slow Scanner →

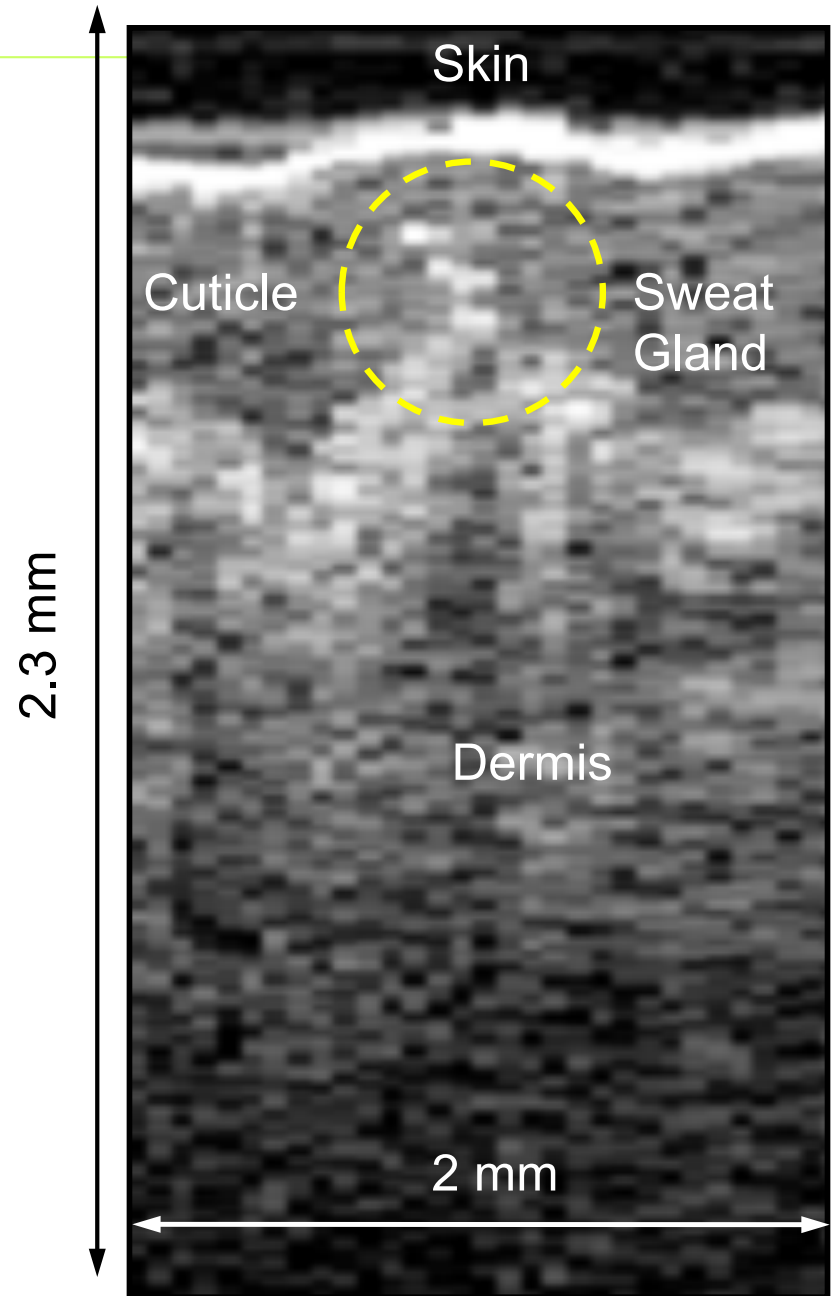


OCT (Optical Coherence Tomography) Image

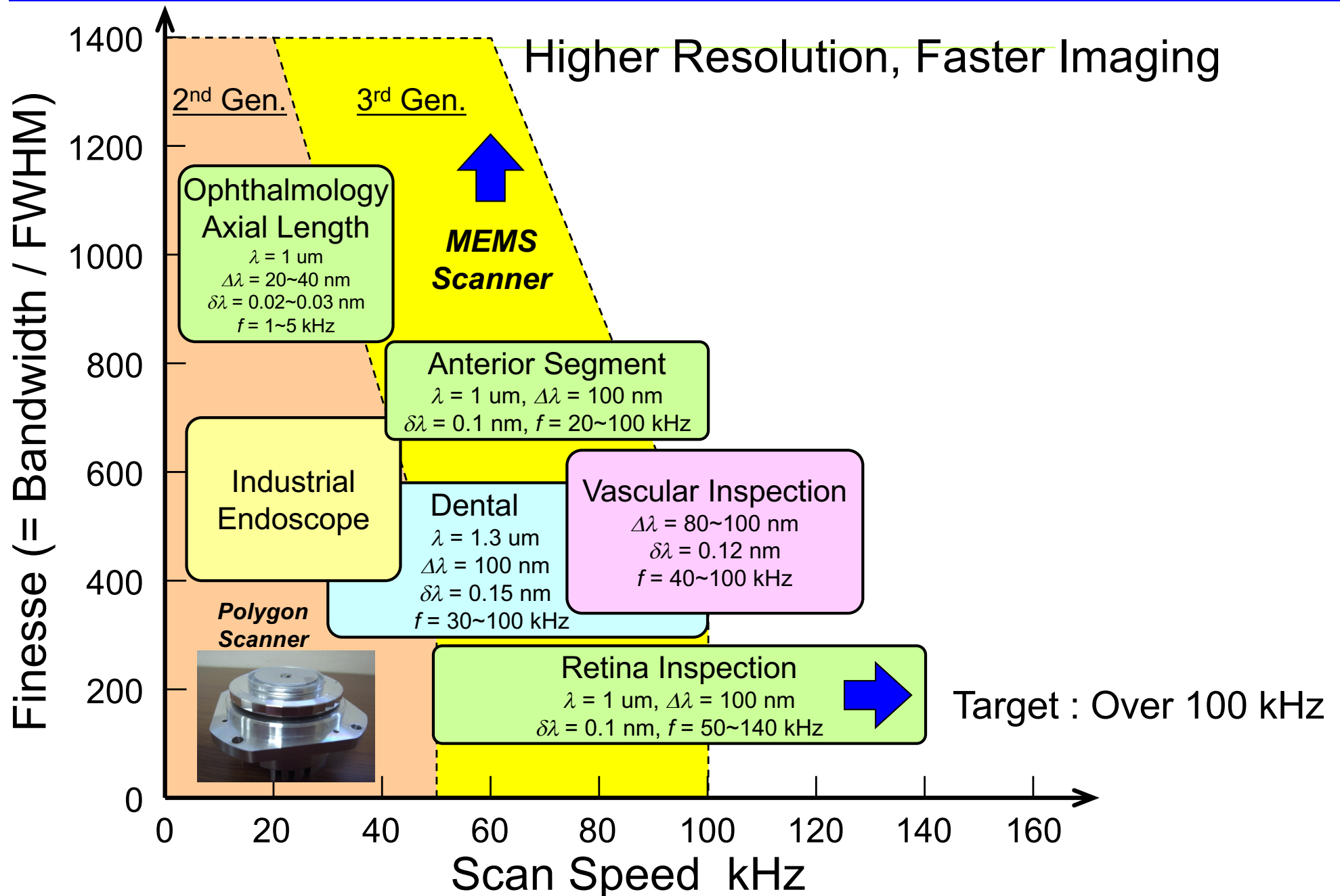


M. Nakada, et al., "Optical Coherence Tomography based on Power-over-fiber MEMS Scanner," *APCOT 2008*, Jun. 22-25 2008.

	Scan Range (mm)	Resolution (um)
Lateral	1.6	40
Depth	1.0 ~ 2.5	8

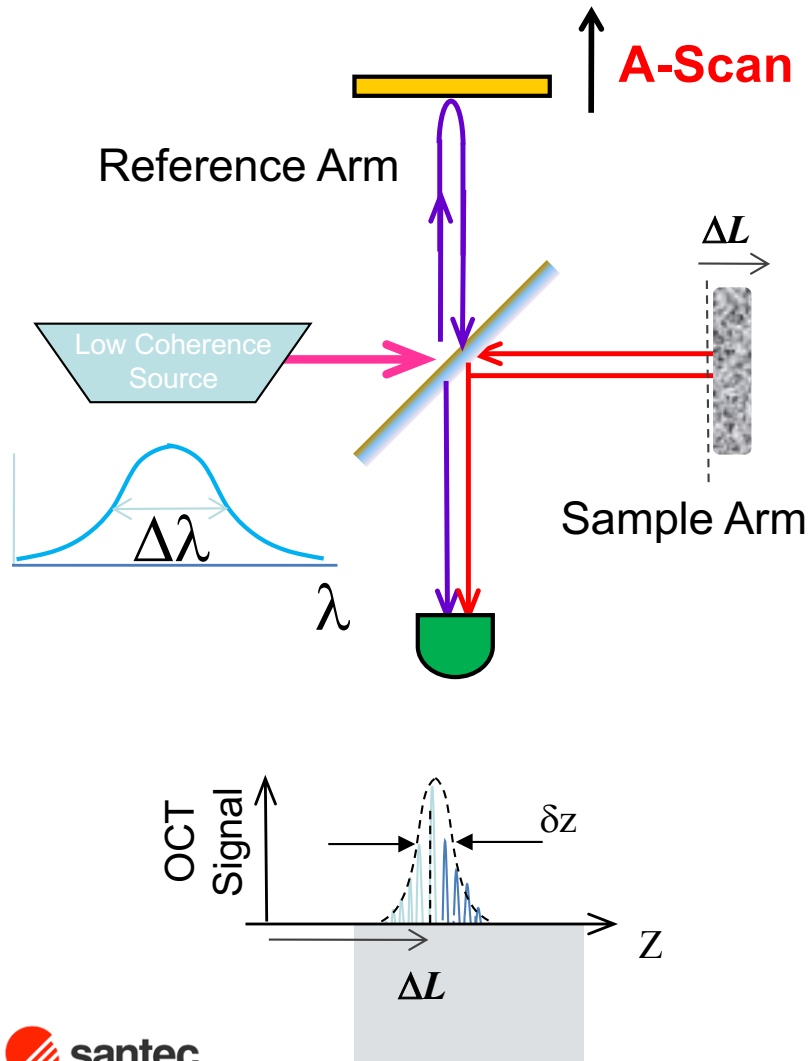


Wavelength-Tunable Laser for OT

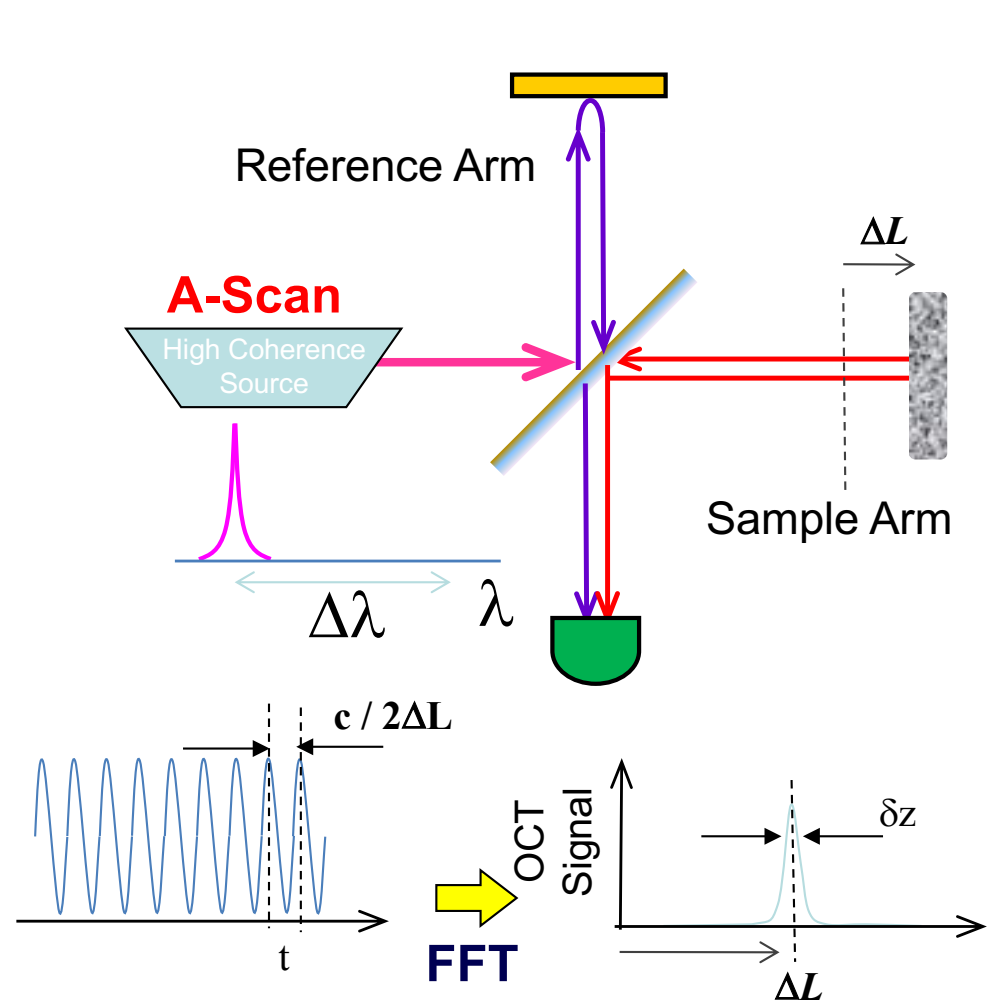


Two OCT Operation Principles

Time-Domain OCT (TD-OCT)



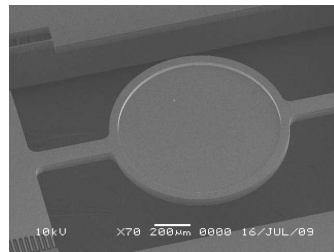
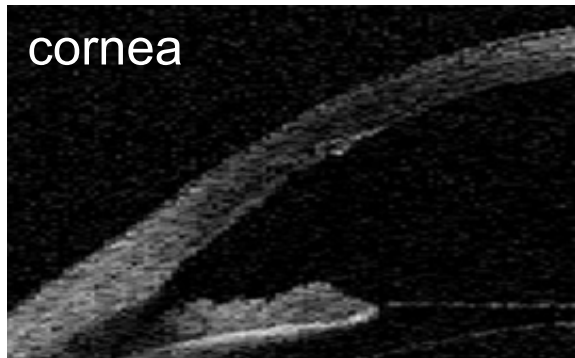
Swept-Source OCT (SS-OCT)



Advantages of SS-OCT

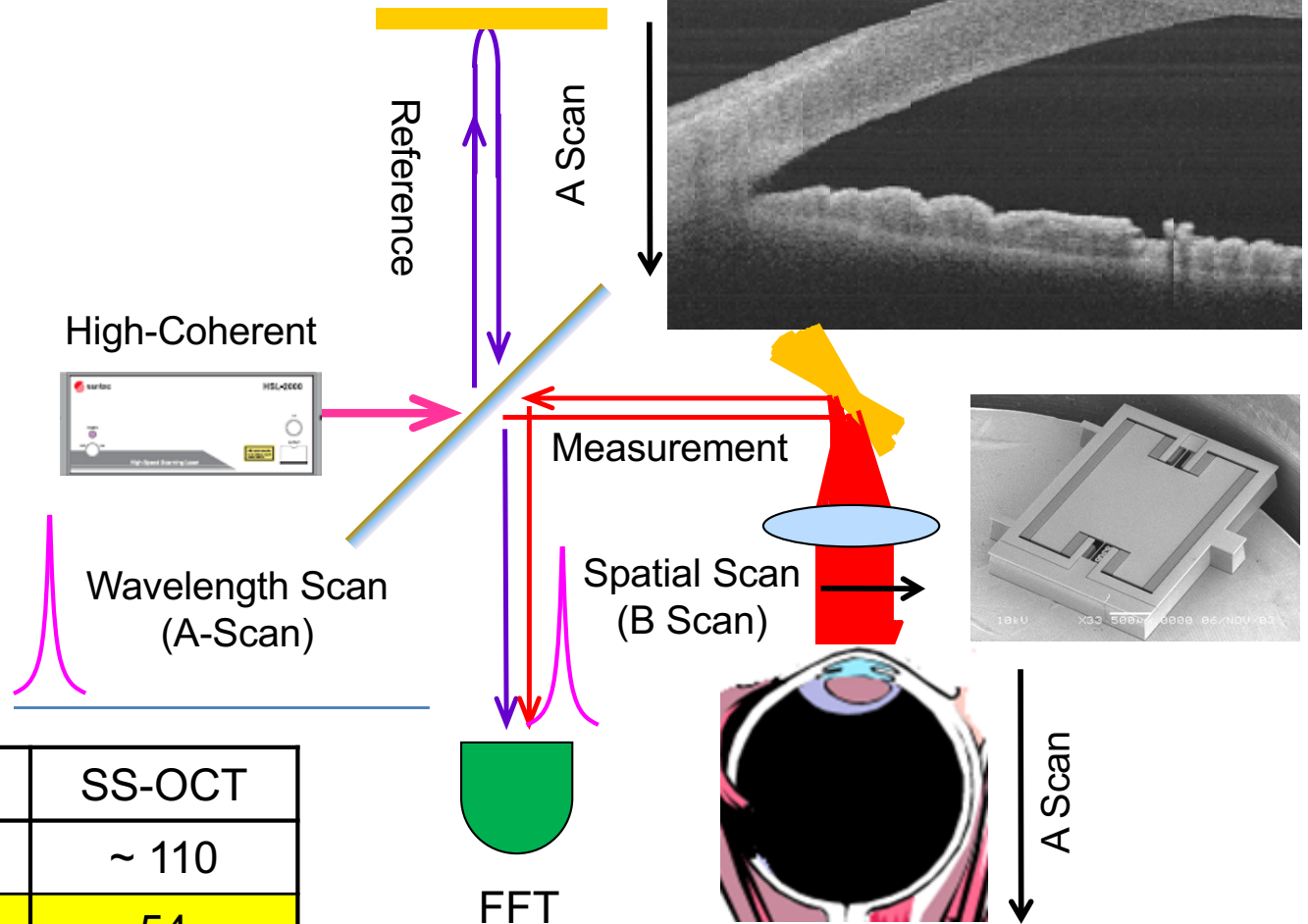
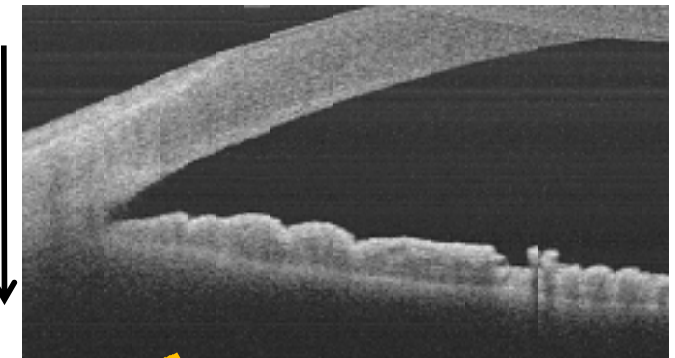
Time-Domain OCT (TD-OCT)

Time-Domain Zeiss Visante OCT



Swept-Source OCT (SS-OCT)

This work



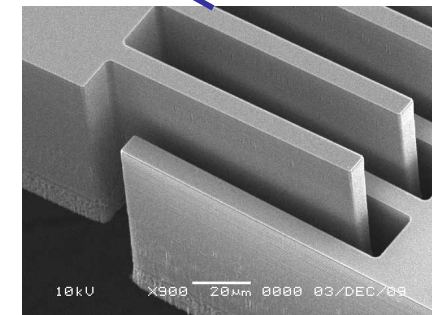
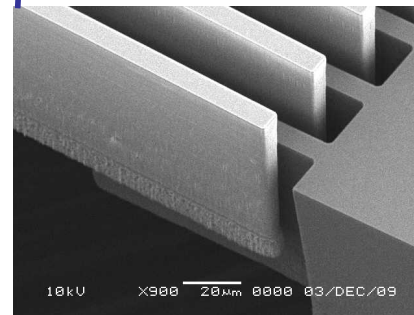
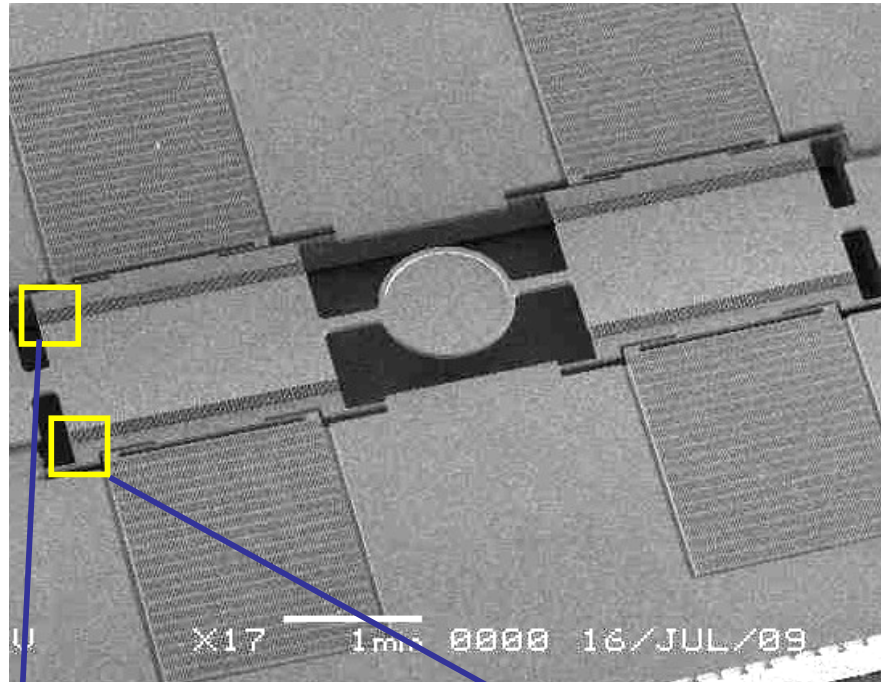
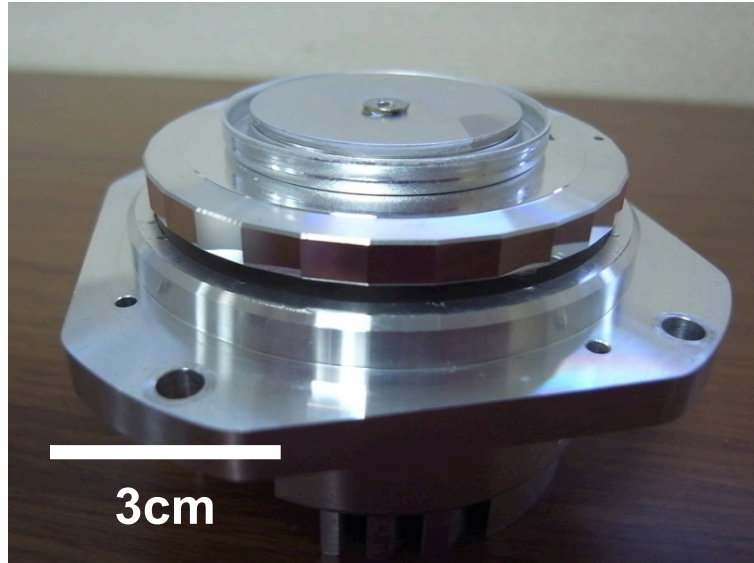
	TD-OCT	SS-OCT
Sensitivity dB	~ 90 dB	~ 110
Frame Rate fps	1	54
Resolution μm	10~15	5~10

Keiji Isamoto, Kohki Totsuka, Tooru Sakai, Takuya Suzuki, Atsushi Morosawa, Changho Chong, Hiroyuki Fujita, Hiroshi Toshiyoshi, "A High Speed MEMS Scanner for 140-kHz SS-OCT," IEEE Int. Conf. on Optical MEMS and Nanophotonics, Istanbul, Turkey, Aug. 8-11, 2011.

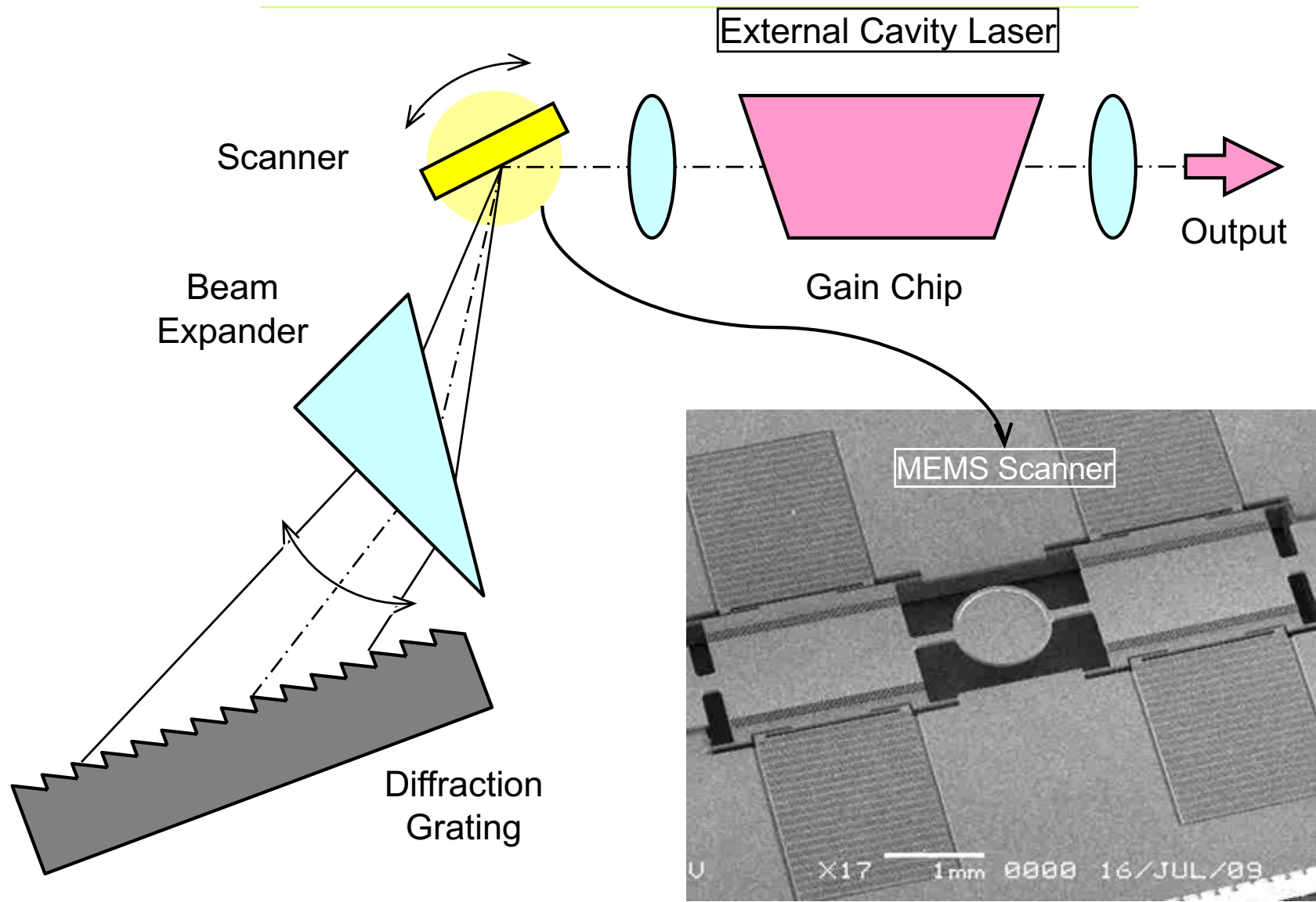
MEMS Scanner to Replace Polygon Mirrors



Fast Operation Speed at 70 kHz

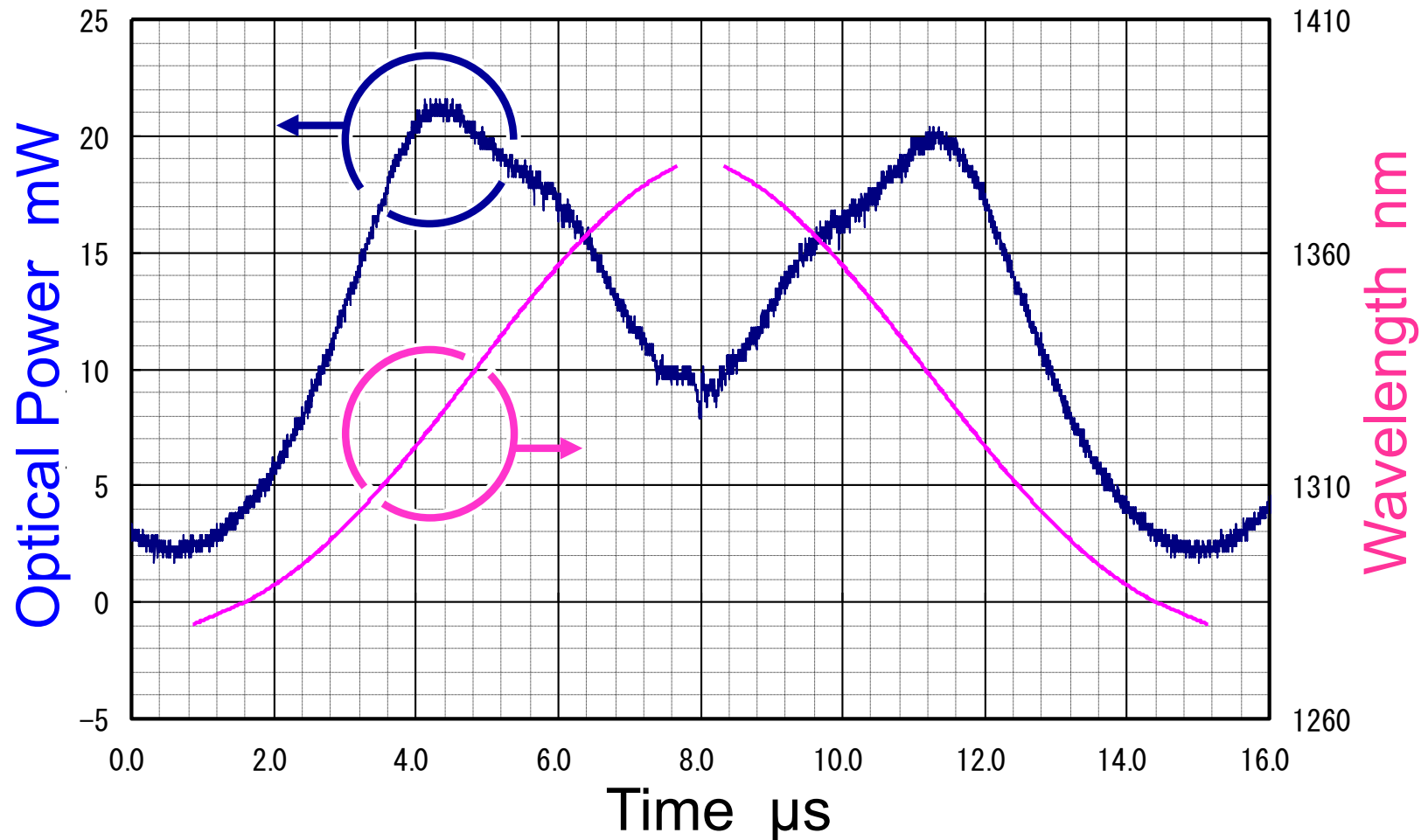


External Cavity Laser for Wavelength Tuning



Wavelength Scan Performance

Mechanical 70 kHz x round-trip scan \rightarrow 140 kHz Sweep
Band Width \sim 100 nm



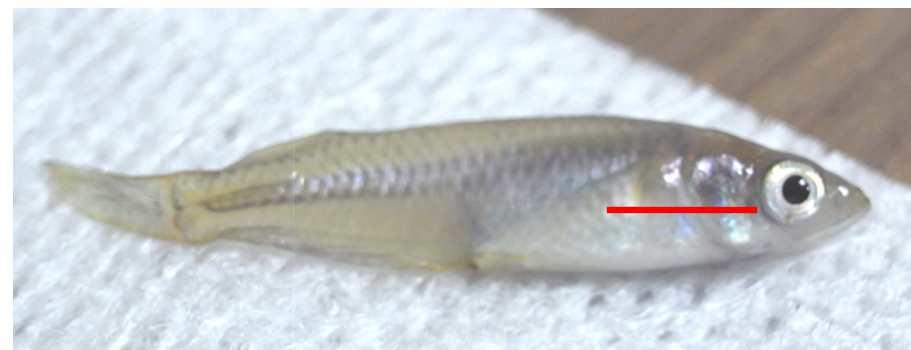
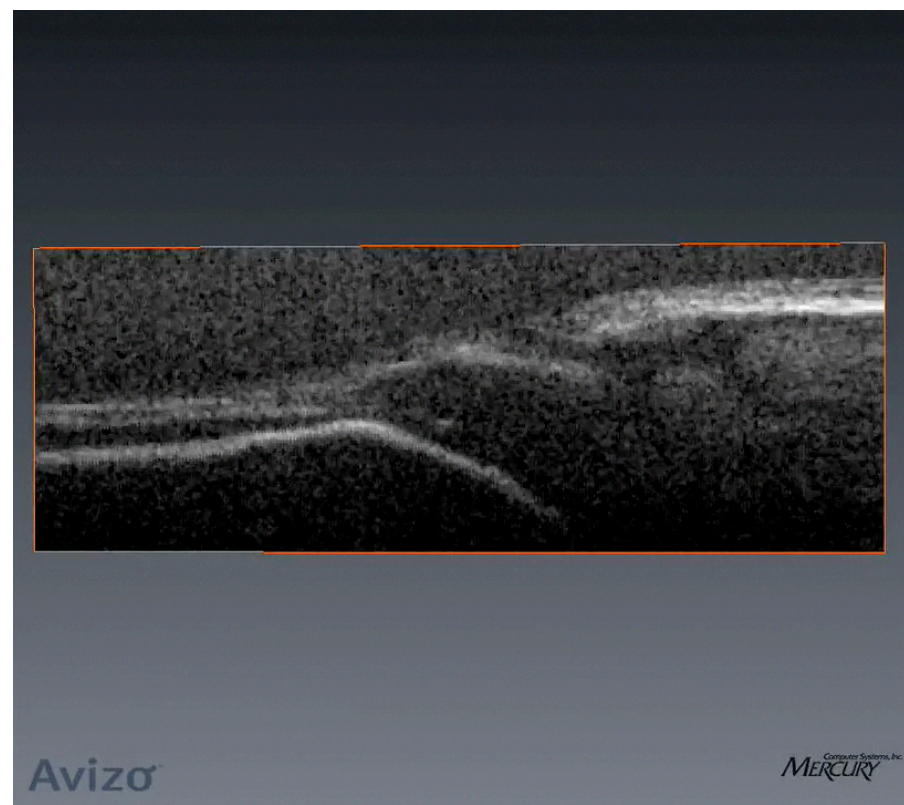
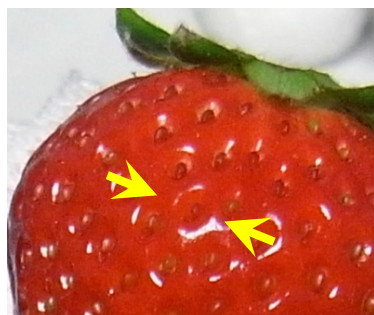
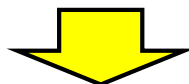
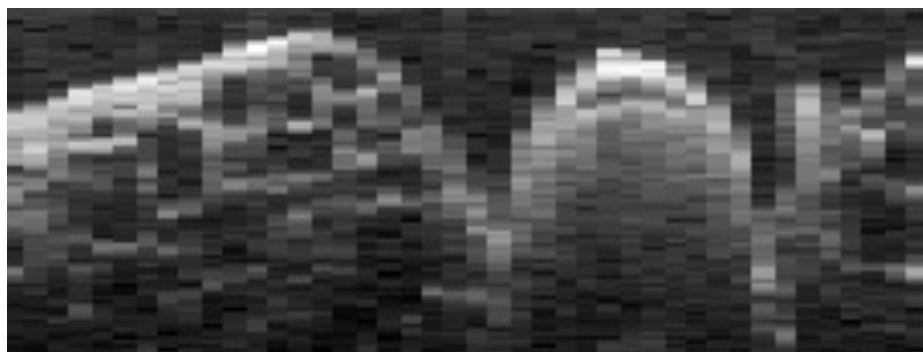
Virtually Slicing Alive



Higher resolution, less invasive, and less expensive than
X-ray CT or Ultrasonic Imagers

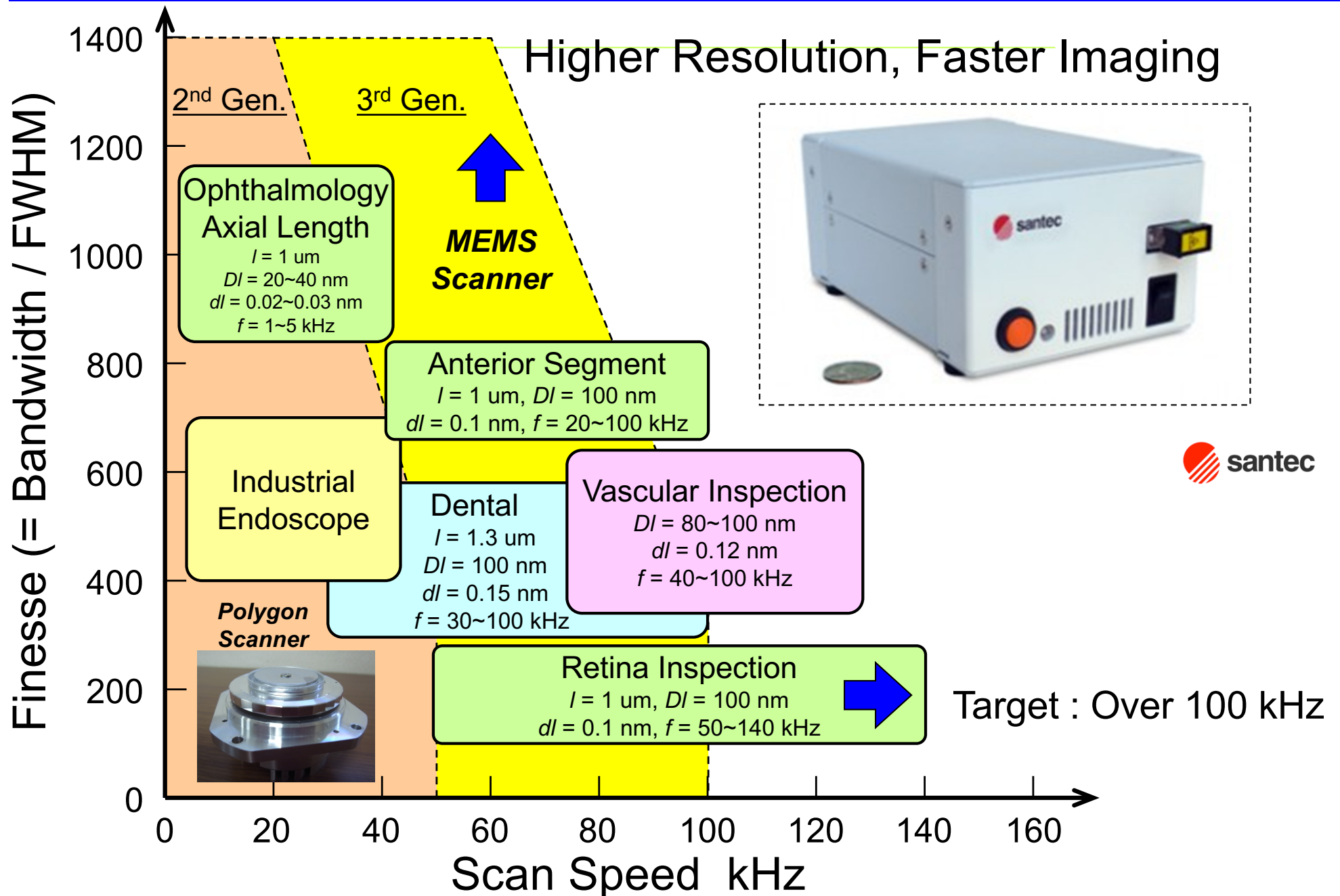
Benefits of Fast OCT Scan

Higher Resolution & Faster Frame Rate



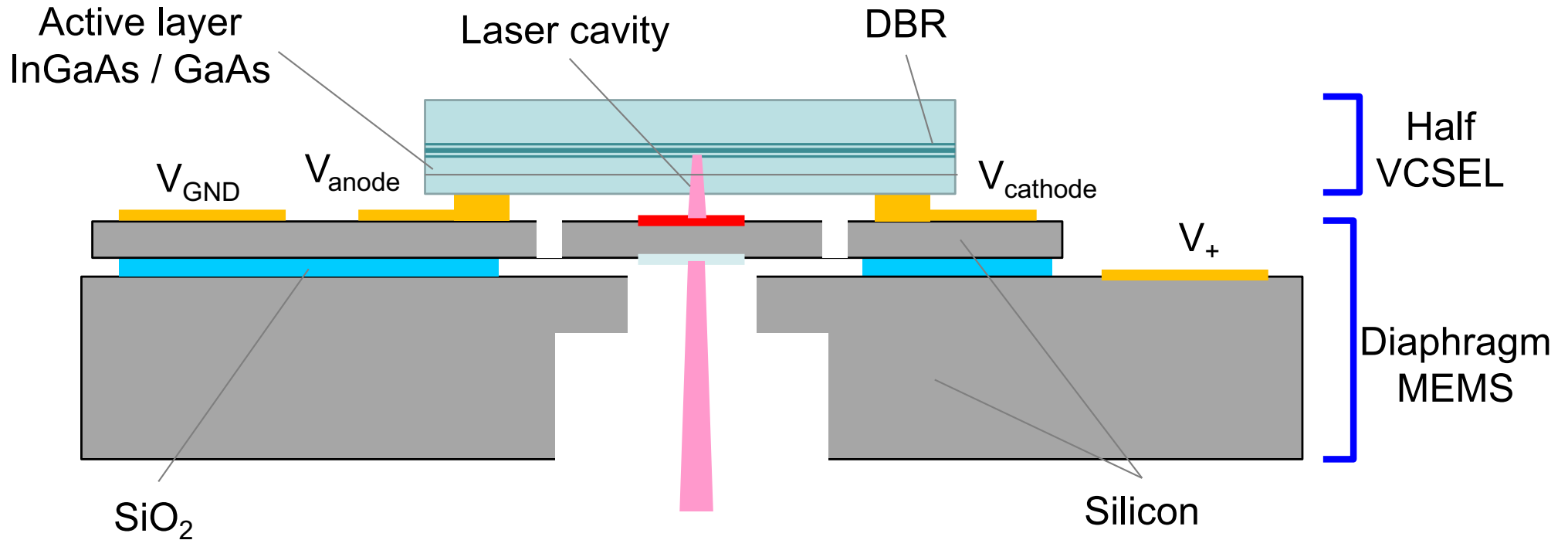
This research is supported by Optoelectronic Industry and Technology Development Association (OITDA), subsidized by JKA through its Promotion funds from KEIRIN RACE.

Wavelength-Tunable Laser for OT



MEMS-based Tunable VCSEL

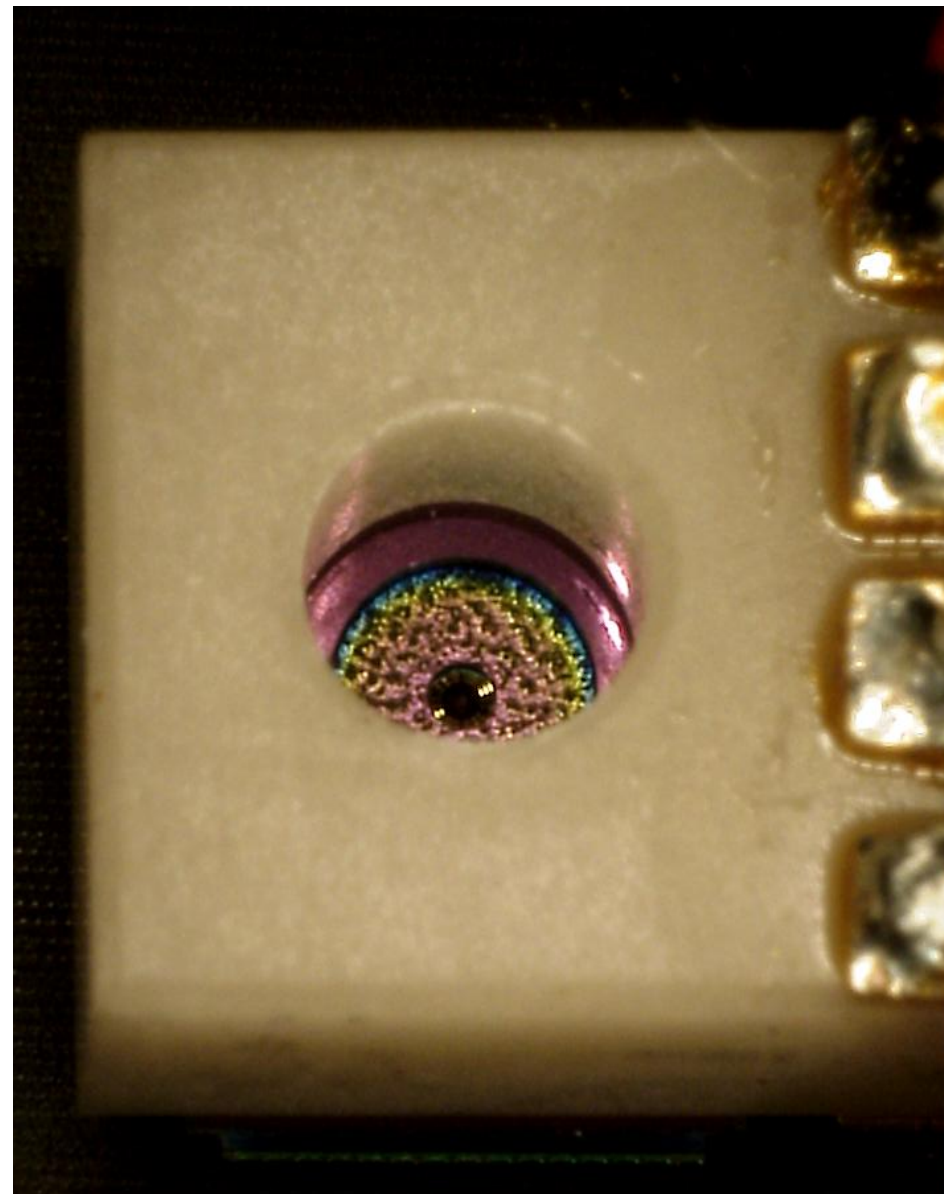
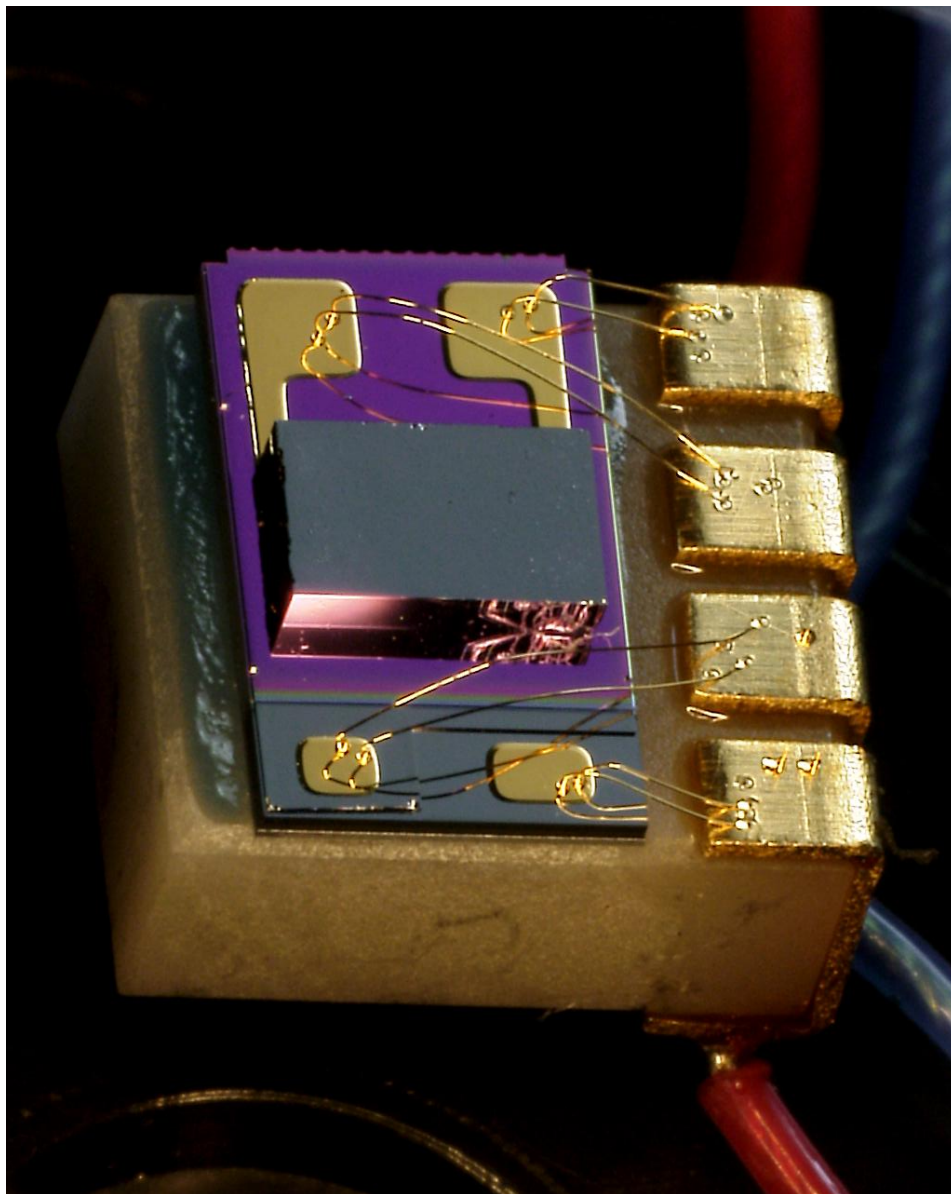
1060 nm wavelength range with InGaAs/GaAs



Keiji Isamoto, Kiyotaka Yamashita, Mohammed Saad Khan, Nicolas Lafitte, Kouki Totsuka, Changho Chong, Nobuhiko Nishiyama, and Hiroshi Toshiyoshi, "A MEMS based electrically pumped tunable VCSEL operating at 1060nm for SS-OCT," SPIE Photonics West 2015 -- MOEMS and Miniaturized Systems XIV --, Feb. 9-12, 2015, The Moscone Center, San Francisco, CA.

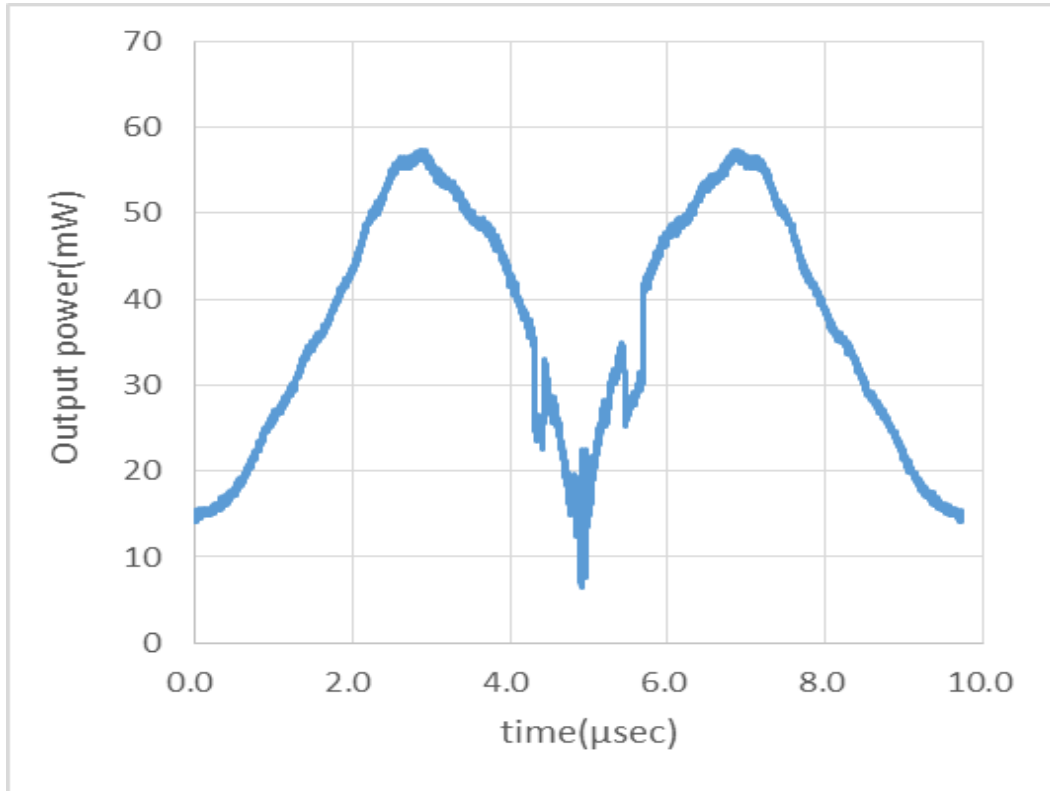
MEMS-based Tunable VCSEL

Device Package (Front / Rear)



Wavelength Tuning Performance

Coherence Length > 100 nm to probe deep inside

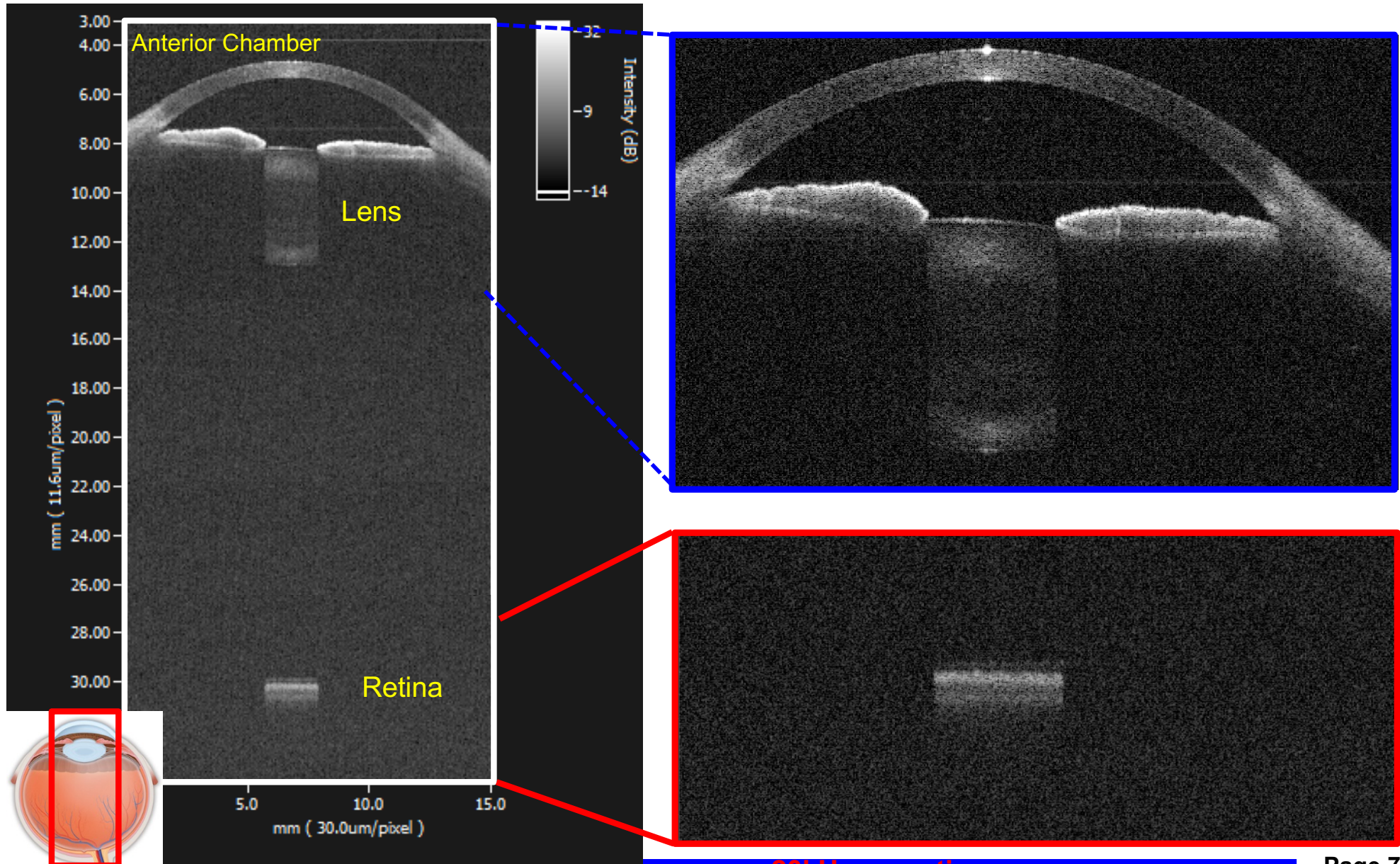


Output Intensity
(Time = Wavelength)

Spec.	Typical
Scan Speed	10 - 200 kHz
Coherence Length	>100 nm
Output Power	40 mW average (2 mW w/o amp)
Wavelength Range	80 nm

Benefits of Long Coherence Length

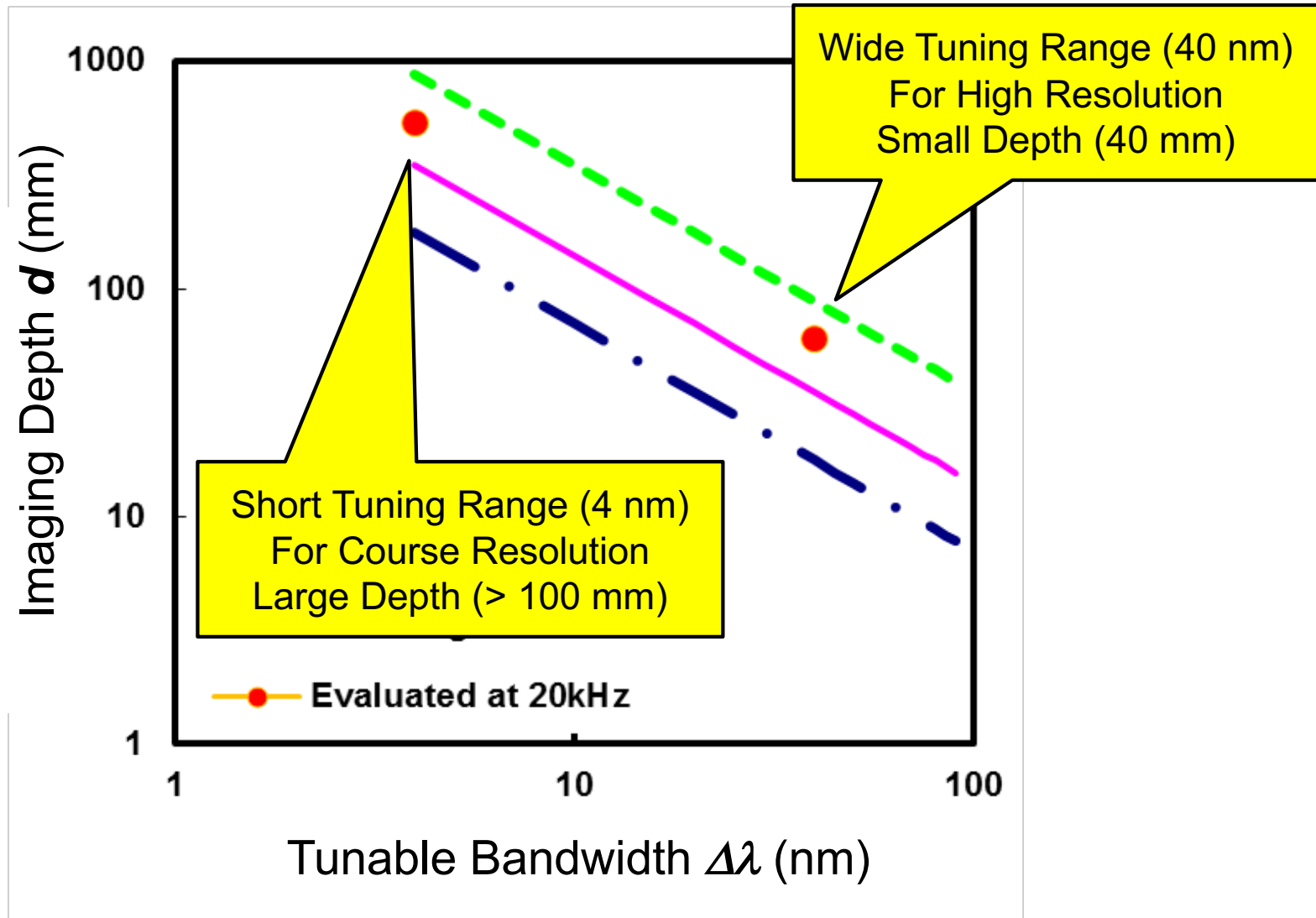
Visualizing Long Distance ... in particular for ophthalmologic examination



20kHz operation

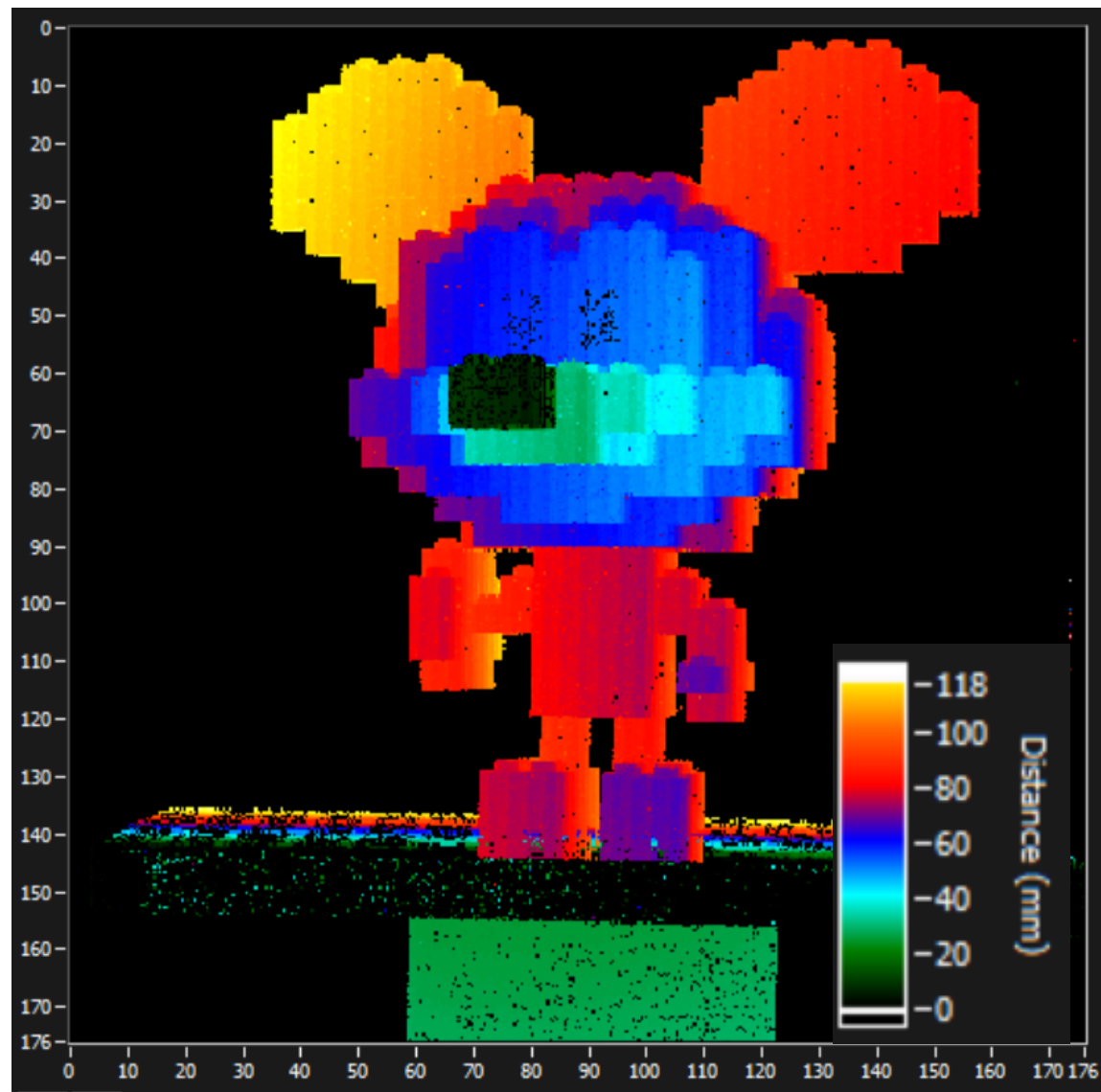
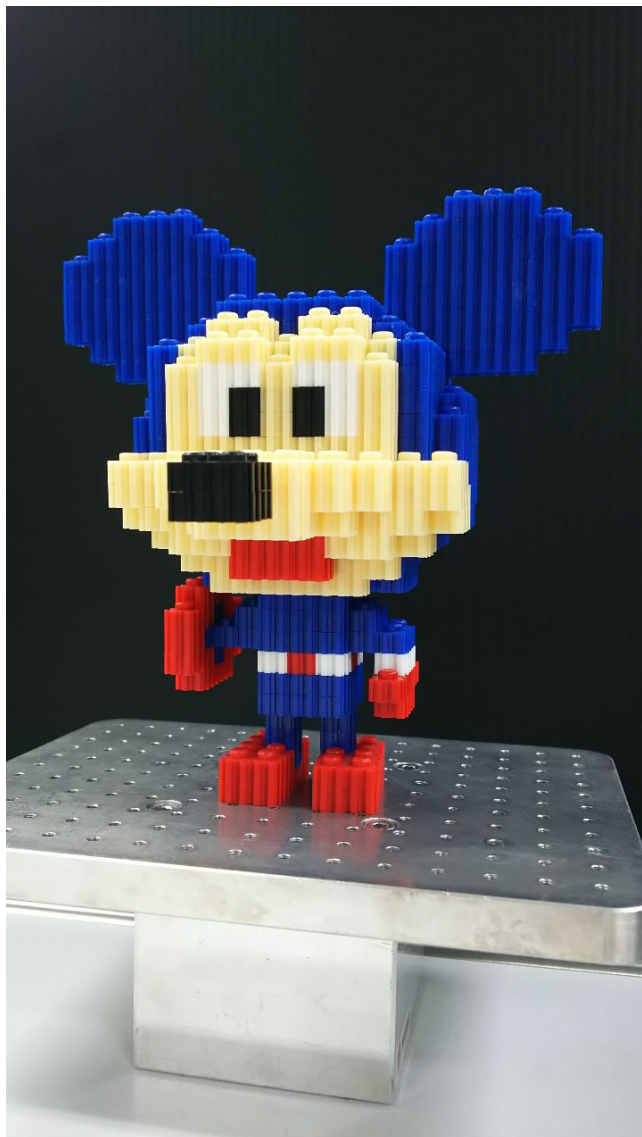
Imaging Depth Scaling

At 500 MHz data sampling with a 50% duty cycle



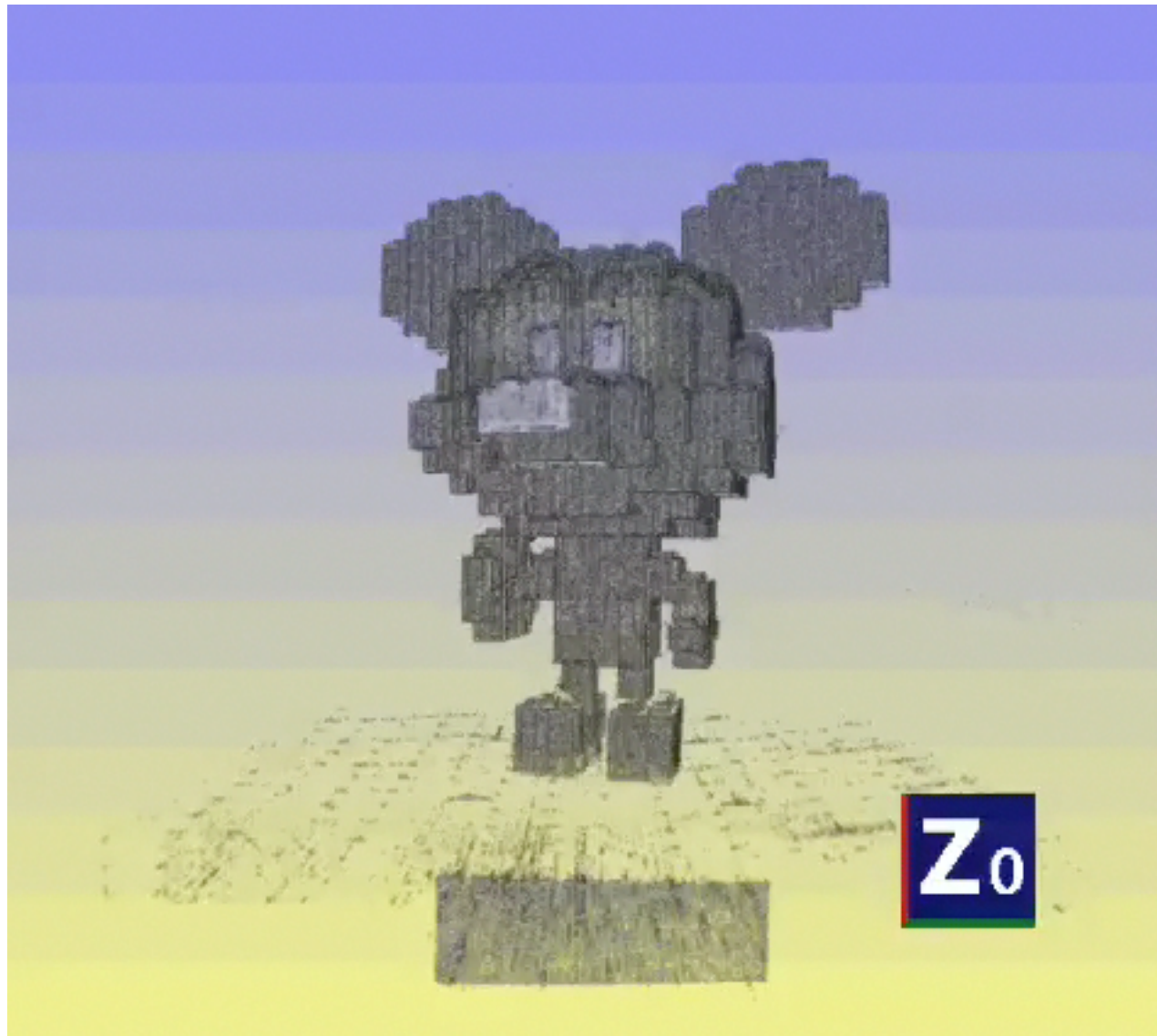
OCT over a Distance (~ 1 m)

$$\Delta\lambda = 4 \text{ nm} \rightarrow d \sim 10 \text{ cm}$$



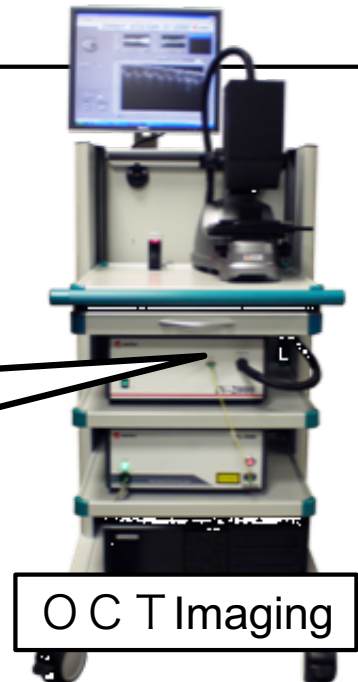
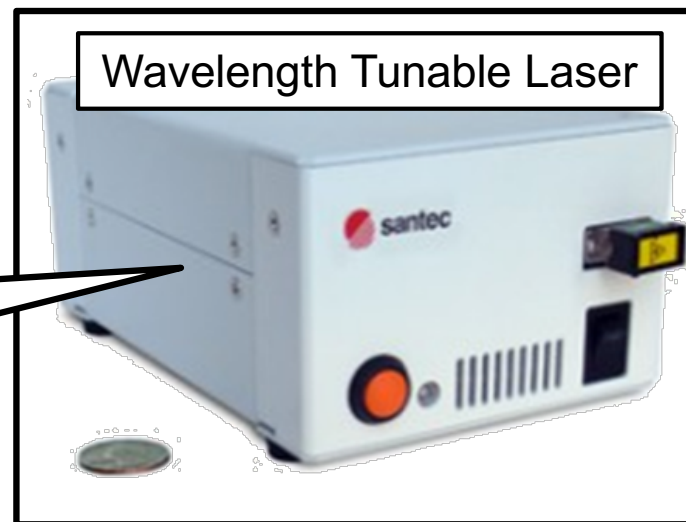
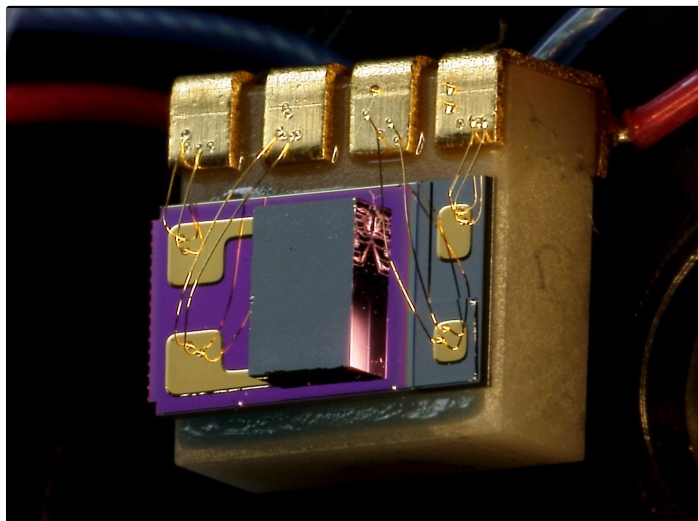
OCT over a Distance (~ 1 m)

$$\Delta\lambda = 4 \text{ nm} \rightarrow d \sim 10 \text{ cm}$$



Overall OCT System Performance

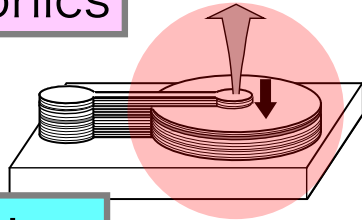
	Experimental Results	Note
Scan Speed	140 kHz	Round-Trip Scan 1310 nm (in Air)
Band Width	100 nm	
OCT Resolution	9 μm	
Spectrum Width	0.25 nm	
Coherence Length	3 mm	
Maximum Power	20 mW	
Dynamic Range	60 dB	



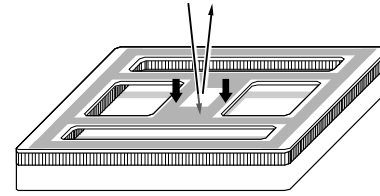
Contents Today

1. MEMS = Micro Electro Mechanical Systems
2. μ -Actuator for Astronomy
3. MEMS at the Beginning = Fiber Telecom
4. Theory of Electrostatic Force
5. More Added Values
- ▶ 6. Summary

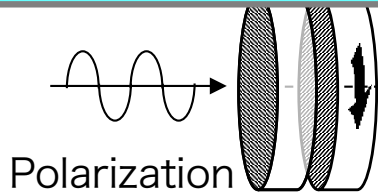
Quantum Photonics



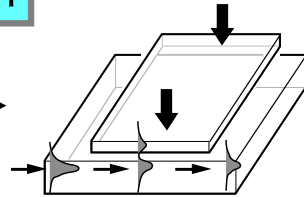
Emission
Absorption



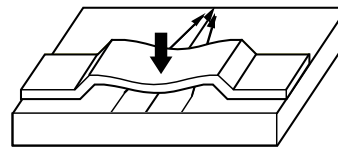
Electromagnetism



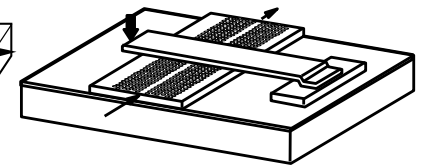
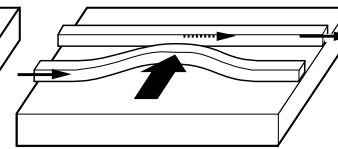
Polarization



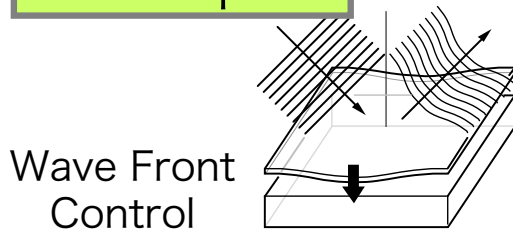
Absorption



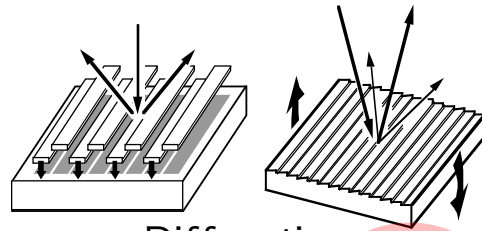
Near Field Optics, Plasmon Resonance, Metamaterial



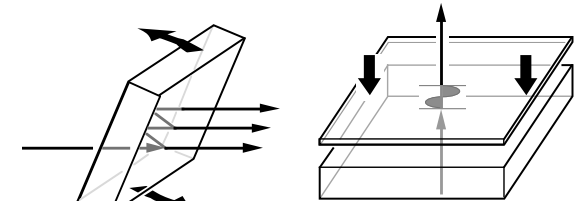
Wave Optics



Wave Front
Control



Diffraction

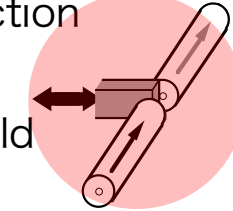


Interference

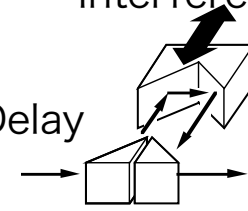
Coupling



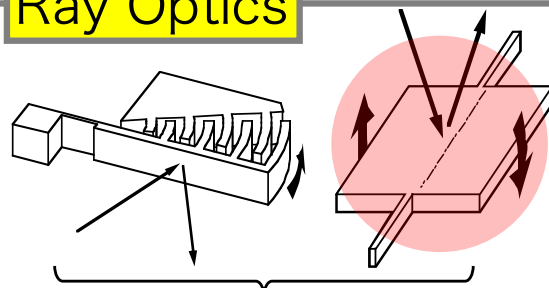
Shield



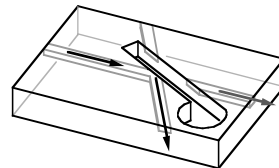
Delay



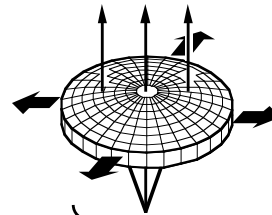
Ray Optics



Reflection



T.I.R



Refraction

